

Memory FeRAM

256K (32 K × 8) Bit I²C

MB85RC256TY

■ DESCRIPTION

The MB85RC256TY is an FeRAM (Ferroelectric Random Access Memory) chip in a configuration of 32,768 words × 8 bits, using the ferroelectric process and silicon gate CMOS process technologies for forming the nonvolatile memory cells.

Unlike SRAM, the MB85RC256TY is able to retain data without using a data backup battery.

The read/write endurance of the nonvolatile memory cells used for the MB85RC256TY has improved to be at least 10¹³ cycles, significantly outperforming other nonvolatile memory products in the number.

The MB85RC256TY does not need a polling sequence after writing to the memory such as the case of Flash memory or E²PROM.

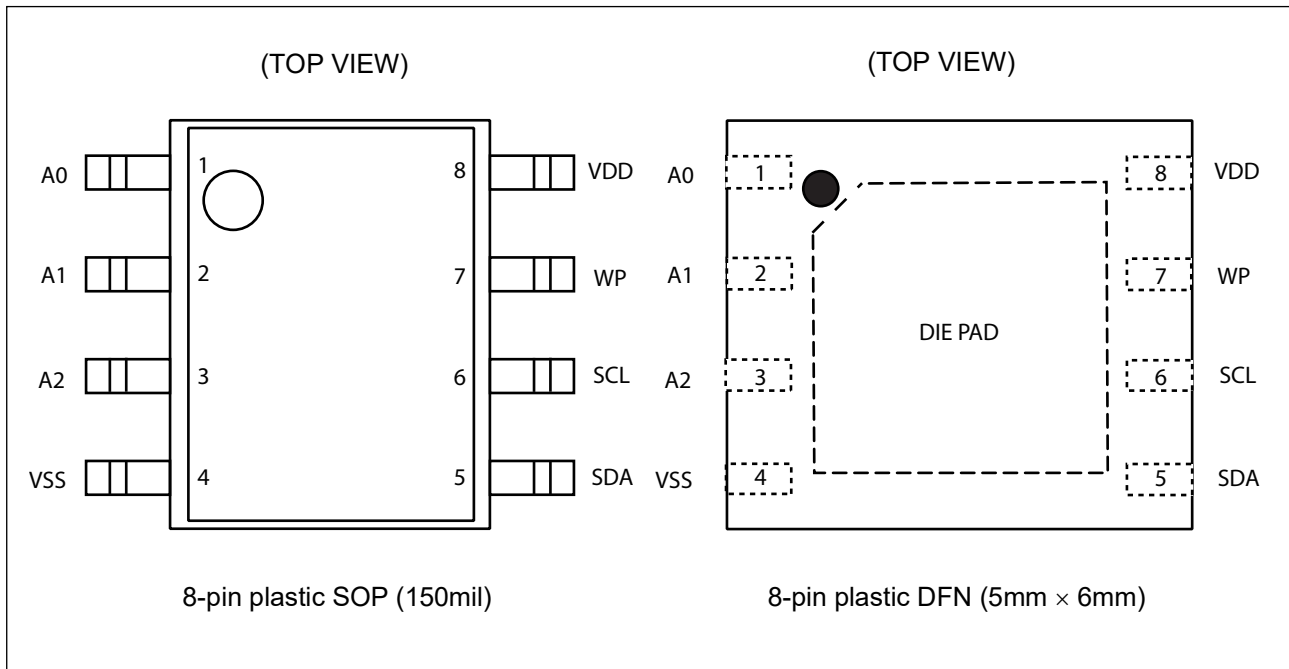
■ FEATURES

- Bit configuration : 32,768 words × 8 bits
- Two-wire serial interface : Fully controllable by two ports: serial clock (SCL) and serial data (SDA).
- Operating frequency : 3.4 MHz (Max @HIGH SPEED MODE)
1 MHz (Max @FAST MODE PLUS)
- Read/write endurance : 10¹³ times(+ 125 °C), 10¹⁴times(+ 85 °C)
- Data retention : 193.9 years (+ 85 °C),
40.7 years(+ 105 °C),
10.1 years(+ 125 °C)
- Operating power supply voltage: 1.8 V to 3.6 V
- Low-power consumption : Operating power supply current 0.23 mA (Typ @3.4 MHz)
0.4 mA (Max @3.4 MHz)
Standby current 14 μA (Typ)
Sleep current 0.24 μA (Typ)
- Operation ambient temperature range : - 40 °C to + 125 °C
- Package : 8-pin plastic SOP (150mil)
8-pin plastic DFN (5mm × 6mm)
RoHS compliant

Fujitsu Semiconductor Memory Solutions Limited has changed its name to RAMXEED Limited. RAMXEED Limited will continue to offer and support existing products while maintaining Fujitsu's part number unchanged.

MB85RC256TY

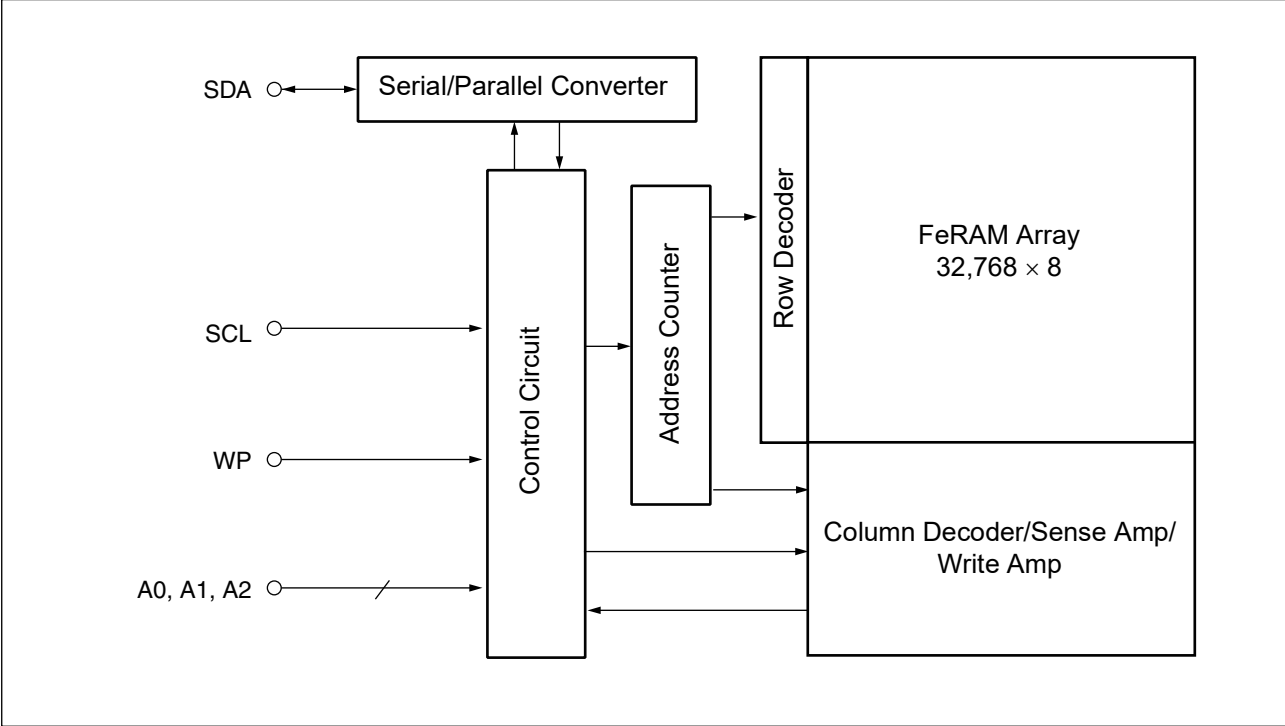
■ PIN ASSIGNMENT



■ PIN FUNCTIONAL DESCRIPTIONS

| Pin Number | Pin Name | Functional Description |
|------------|----------|--|
| 1 to 3 | A0 to A2 | Device Address pins The MB85RC256TY can be connected to the same data bus up to 8 devices. Device addresses are used in order to identify each of these devices. Connect these pins to VDD pin or VSS pin externally. Only if the combination of VDD and VSS pins matches Device Address Code inputted from the SDA pin, the device operates. In the open pin state, A0, A1 and A2 pins are internally pulled-down and recognized as the "L" level. |
| 4 | VSS | Ground pin |
| 5 | SDA | Serial Data I/O pin This is an I/O pin which performs bidirectional communication for both memory address and writing/reading data. It is possible to connect multiple devices. It is an open drain output, so a pull-up resistor is required to be connected to the external circuit. |
| 6 | SCL | Serial Clock pin This is a clock input pin for input/output serial data. Data is sampled on the rising edge of the clock and output on the falling edge. |
| 7 | WP | Write Protect pin When the Write Protect pin is the "H" level, the writing operation is disabled. When the Write Protect pin is the "L" level, the entire memory region can be overwritten. The reading operation is always enabled regardless of the Write Protect pin input level. The Write Protect pin is internally pulled down to VSS pin, and that is recognized as the "L" level (write enabled) when the pin is the open state. |
| 8 | VDD | Supply Voltage pin |

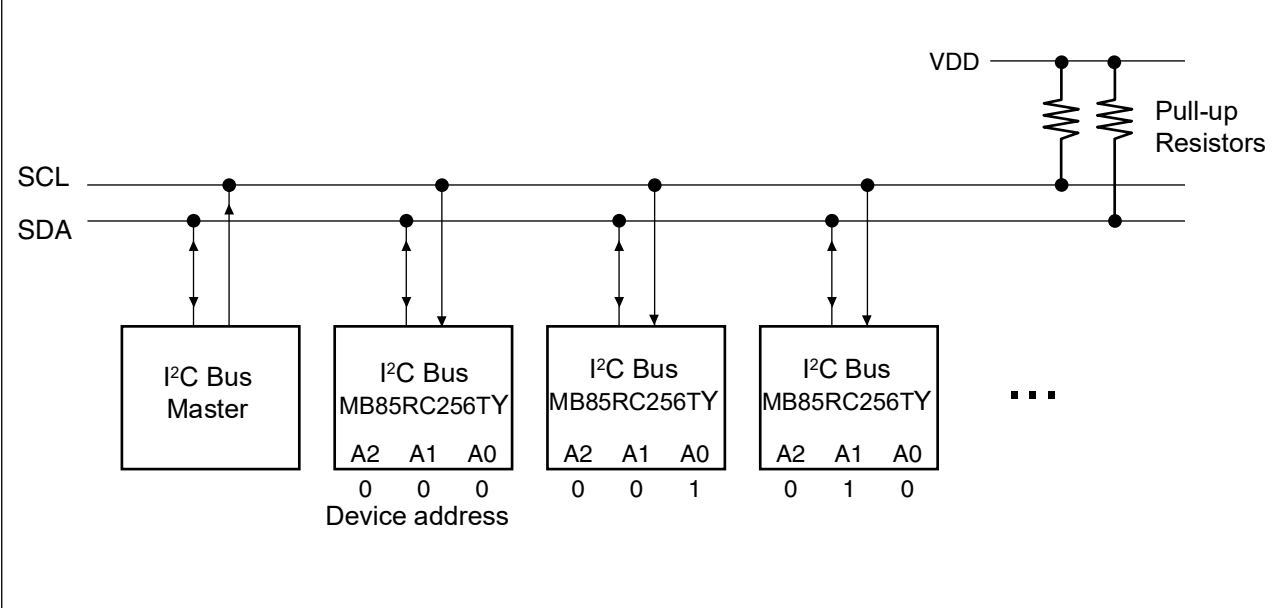
■ BLOCK DIAGRAM



■ I²C (Inter-Integrated Circuit)

The MB85RC256TY has the two-wire serial interface; the I²C bus, and operates as a slave device. The I²C bus defines communication roles of “master” and “slave” devices, with the master side holding the authority to initiate control. Furthermore, the I²C bus connection is possible where a single master device is connected to multiple slave devices in a party-line configuration. In this case, it is necessary to assign a unique device address to the slave device, the master side starts communication after specifying the slave to communicate by addresses.

● I²C Interface System Configuration Example



■ I²C COMMUNICATION PROTOCOL

The I²C bus is a two wire serial interface that uses a bidirectional data bus (SDA) and serial clock (SCL). A data transfer can only be initiated by the master, which will also provide the serial clock for synchronization. The SDA signal should change while the SCL is the "L" level. However, as an exception, when starting and stopping communication sequence, the SDA is allowed to change while the SCL is the "H" level.

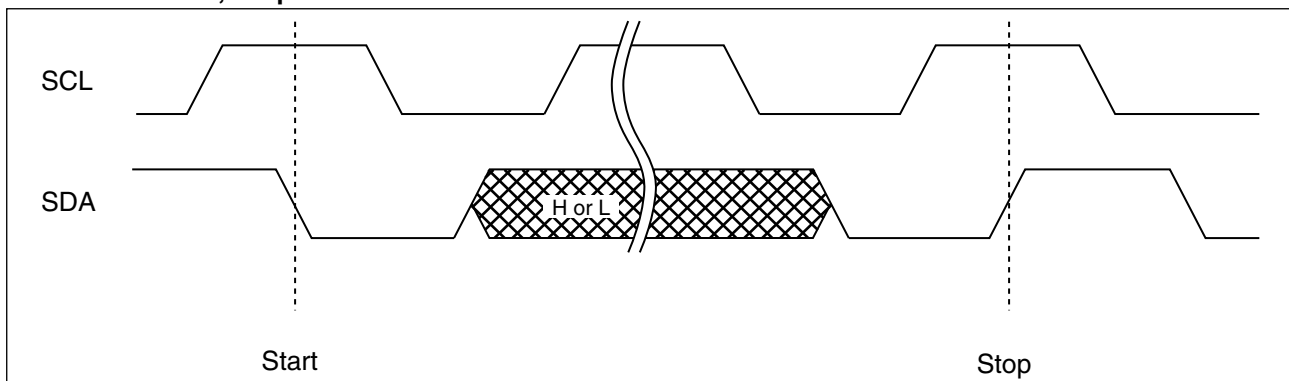
- Start Condition

To start read or write operations by the I²C bus, change the SDA input from the "H" level to the "L" level while the SCL input is in the "H" level.

- Stop Condition

To stop the I²C bus communication, change the SDA input from the "L" level to the "H" level while the SCL input is in the "H" level. In the reading operation, inputting the stop condition finishes reading and enters the standby state. In the writing operation, inputting the stop condition finishes inputting the rewrite data and enters the standby state.

- Start Condition, Stop Condition



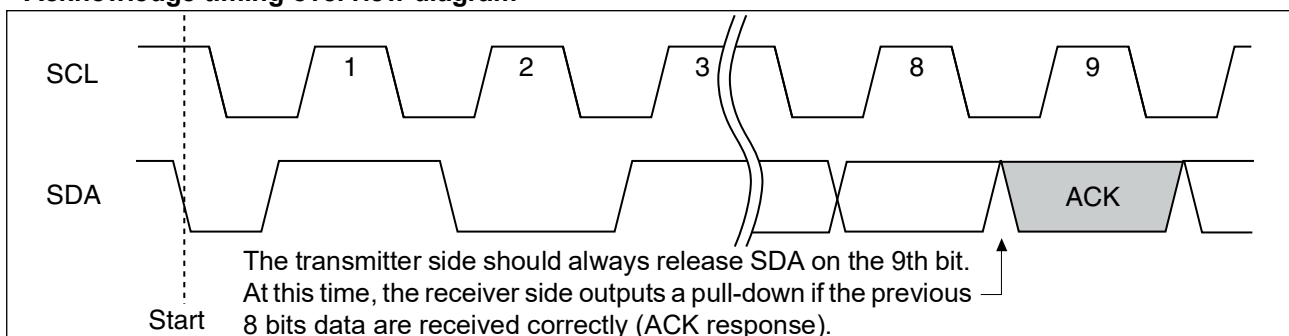
Note : At the write operation, the FeRAM device does not need the programming wait time (t_{wc}) after issuing the Stop Condition.

■ ACKNOWLEDGE (ACK)

In the I²C bus, serial data including memory address or memory information is sent and received in units of 8 bits. The acknowledge signal indicates that every 8 bits of the data is successfully sent and received. The receiver side usually outputs the "L" level every time on the 9th SCL clock after each 8 bits are successfully transmitted and received. On the transmitter side, the bus is temporarily released to Hi-Z every time on this 9th clock to allow the acknowledge signal to be received and checked. During this Hi-Z released period, the receiver side pulls the SDA line down to indicate the "L" level that the previous 8 bits communication is successfully received.

In case the slave side receives Stop condition before sending or receiving the ACK "L" level, the slave side stops the operation and enters to the standby state. On the other hand, the slave side releases the bus state after sending or receiving the NACK "H" level. The master side generates Stop condition or Start condition in this released bus state.

- Acknowledge timing overview diagram



■ DEVICE ADDRESS WORD (Slave address)

Following the start condition, the master inputs the 8 bits device address word to start I²C communication. The device address word (8 bits) consists of a device Type code (4 bits), device address code (3 bits) and a read/write code (1 bit).

- Device Type Code (4 bits)

The upper 4 bits of the device address word are a device type code that identifies the device type, and are fixed at "1010" for the MB85RC256TY.

- Device Address Code (3 bits)

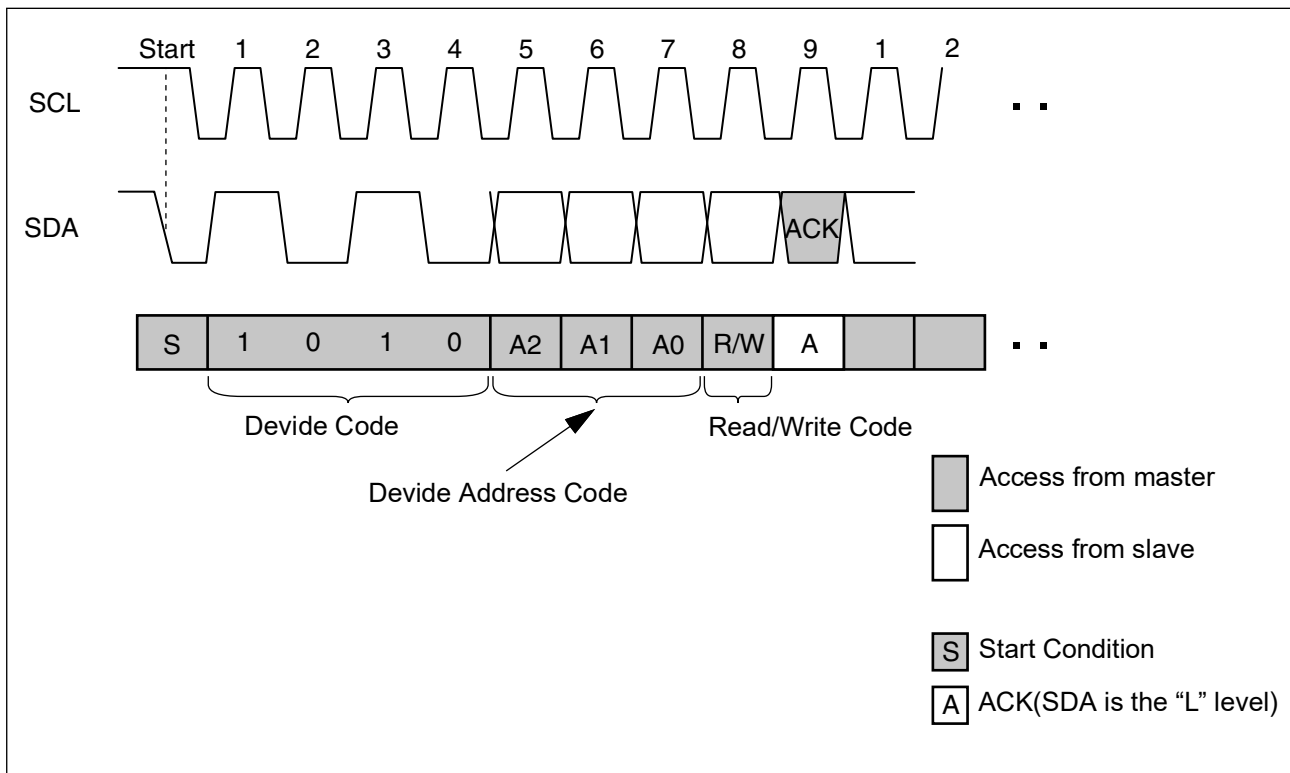
Following the device type code, the 3 bits of the device address code are input in order of A2, A1 and A0. The device address code identifies one device from up to eight devices connected to the bus. Each MB85RC256TY is given a unique 3 bits code on the device address pin (external hardware pin A2, A1 and A0). The slave only responds if the received device address code is equal to this unique 3 bits code.

- Read/Write Code (1 bit)

The 8th bit of the device address word is the R/W (read/write) code. When the R/W code is "0", a write operation is enabled, and the R/W code is "1", a read operation is enabled for the MB85RC256TY.

It turns to a stand-by state if the device code is not "1010" or device address code does not equal to pin A2, A1 and A0.

• Device Address Word



■ DATA STRUCTURE

In the I²C bus, the acknowledge “L” level is output on the 9th bit by a slave, after the 8 bits of the device address word following the start condition are input by a master. After confirming the acknowledge response by the master, the master outputs 8 bits × 2 memory address to the slave. When the each memory address input ends, the slave again outputs the acknowledge “L” level. After this operation, the I/O data follows in units of 8 bits, with the acknowledge “L” level output after every 8 bits.

It is determined by the R/W code whether the data line is driven by the master or the slave. However, the clock line shall be driven by the master. For a write operation, the slave will accept 8 bits from the master, then send an acknowledge. If the master detects the acknowledge, the master will transfer the next 8 bits. For a read operation, the slave will place 8 bits on the data line, then wait for an acknowledge from the master.

■ FeRAM ACKNOWLEDGE -- POLLING NOT REQUIRED

The MB85RC256TY performs the high speed write operations, so any waiting time for an ACK polling* does not occur.

*: In E²PROM, the Acknowledge Polling is performed as a progress check whether rewriting is executed or not. It is normal to judge by the 9th bit of Acknowledge whether rewriting is performed or not after inputting the start condition and then the device address word (8 bits) during rewriting.

■ WRITE PROTECT (WP)

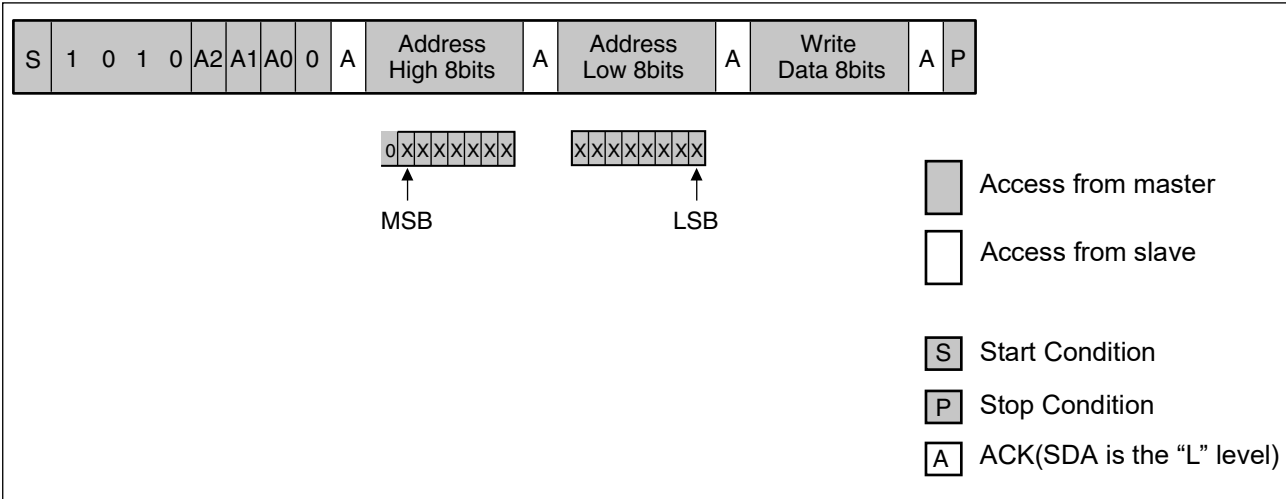
The entire memory array can be write protected using the Write Protect pin. When the Write Protect pin is set to the “H” level, the entire memory array will be write protected. When the Write Protect pin is the “L” level, the entire memory array will be rewritten. Reading is allowed regardless of the WP pin's “H” level or “L” level.

Note : The Write Protect pin is pulled down internally to the VSS pin, therefore if the Write Protect pin is open, the pin status is detected as the “L” level (write enabled).

■ COMMAND

• Byte Write

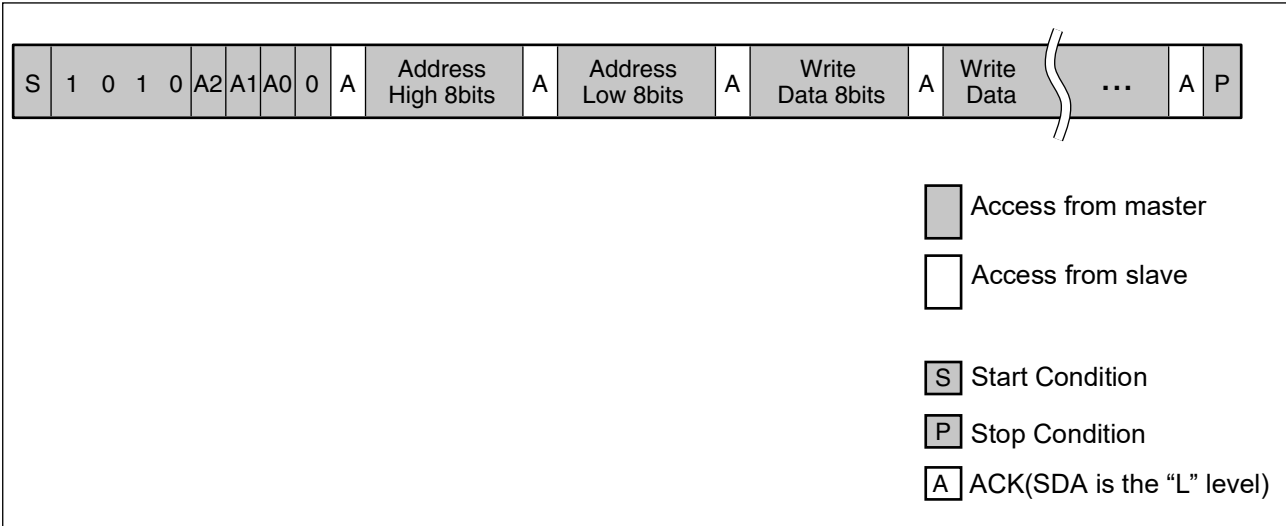
If the device address word (R/W “0” input) is sent following the start condition, the slave responds with an ACK. After this ACK, write addresses and data are sent in the same way, and the write ends by generating a stop condition at the end.



Note : In the MB85RC256TY, input “0” to the most significant bit of the higher address byte because the address is expressed with 15 bits.

• Page Write

If additional 8 bits are continuously sent after the same command (except stop condition) as Byte Write, a page write is performed. The memory address rolls over to first memory address (0000_H) at the end of the address. Therefore, if more than 32 Kbytes are sent, the data is overwritten in order starting from the start of the memory address that was written first. Because FeRAM performs the high-speed write operations, the data will be written to FeRAM right after the ACK response finished.

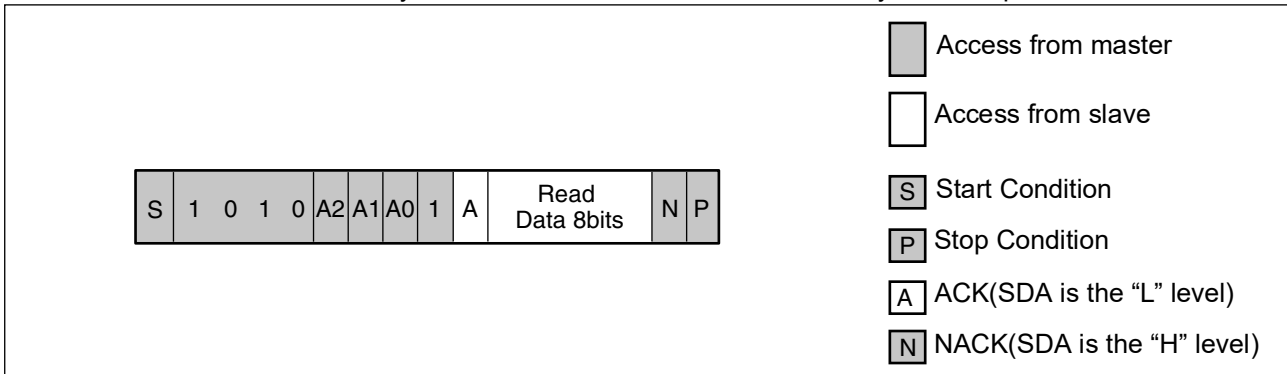


Note: It is not necessary to take a period for internal write operation cycles from the buffer to the memory after the stop condition is generated.

MB85RC256TY

- Current Address Read

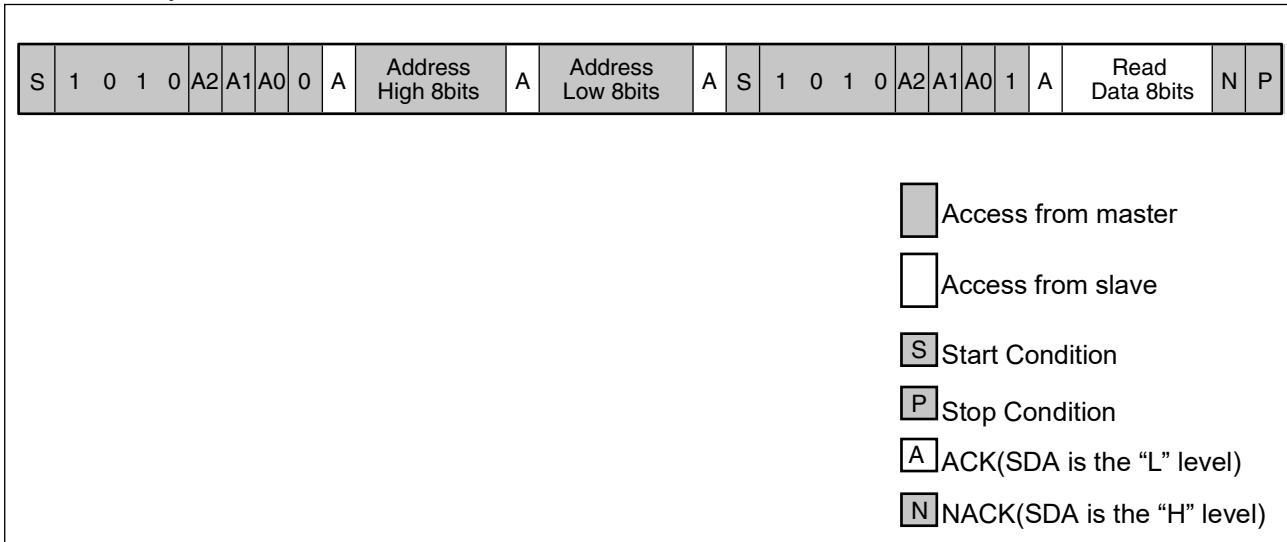
When the previous write or read operation finishes successfully up to the stop condition and assumes the last accessed address is “n”, then the address at “n+1” is read by sending the following command unless turning the power off. If the memory address is last address, the address counter will roll over to (0000_H). The current address in memory address buffer is undefined immediately after the power is turned on.



- Random Read

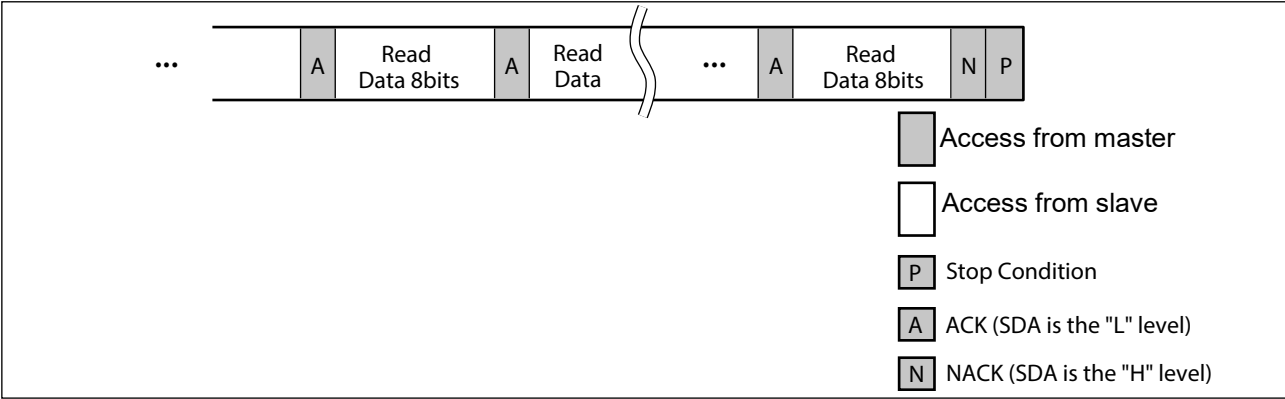
The one byte of data from the memory address saved in the memory address buffer can be read out synchronously to SCL by specifying the address in the same way as for a write, and then issuing another start condition and sending the Device Address Word (R/W “1” input).

The final NACK (SDA is the “H” level) is issued by the receiver that receives the data. In this case, this bit is issued by the master side.



• Sequential Read

Data can be received continuously following the Device address word (R/W "1" input) after specifying the address in the same way as for Random Read. If the read reaches the end of address, the internal read address automatically rolls over to first memory address (0000H) and keeps reading.

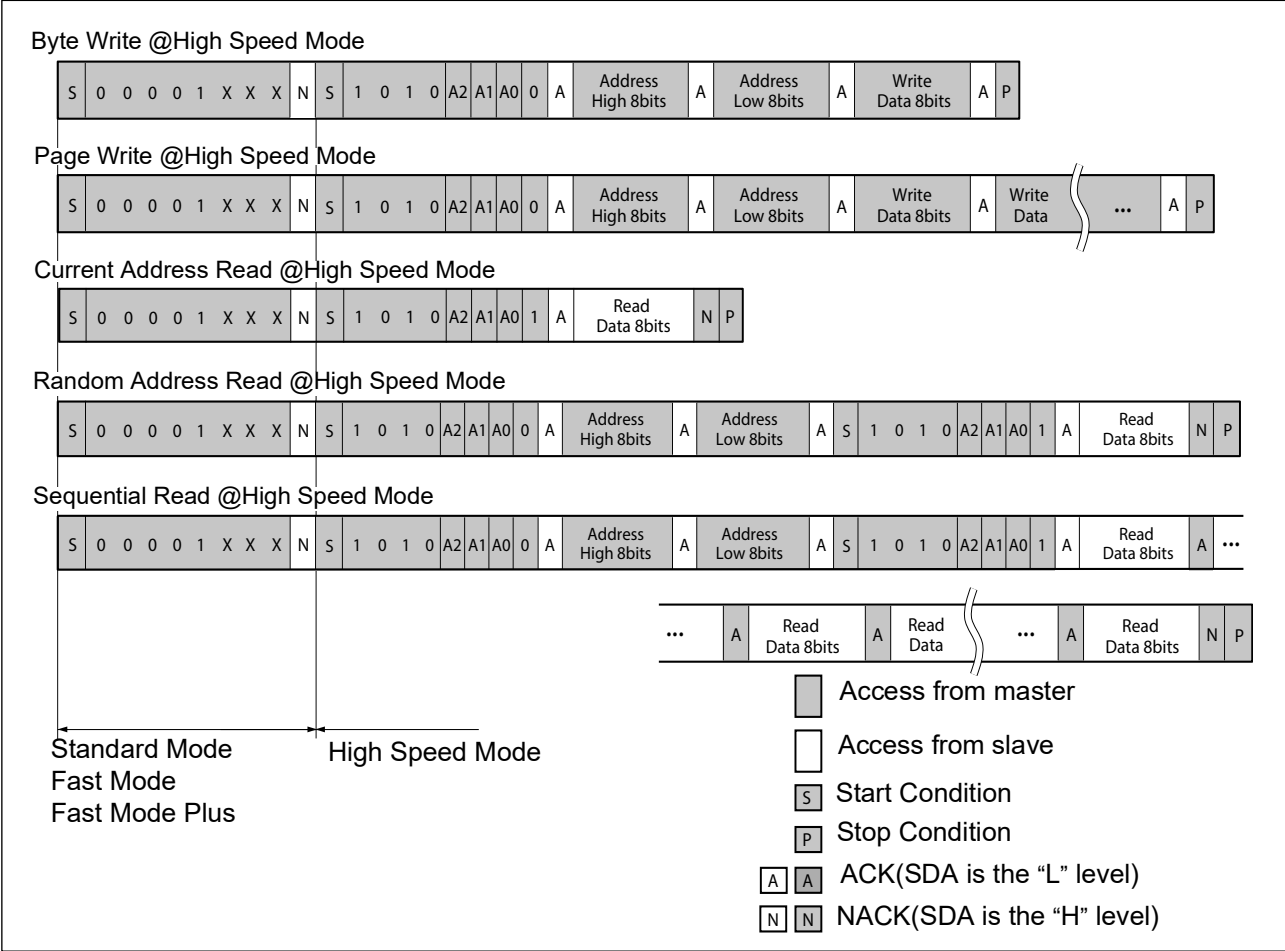


• High Speed Mode

MB85RC256TY supports High Speed mode up to 3.4 MHz. By sending an entry command (0000 1XXX) after start condition from the master side, it informs to the slave that the data transmission with High Speed mode will start.

Since there is no slave side which is allowed to respond to this entry command, NACK response continues from the slave side. After the master side recognizes this NACK response, the master side changes its state to High Speed mode and enables the bidirectional communication up to 3.4 MHz.

By sending Stop condition, it exits out of the state in High Speed communication.



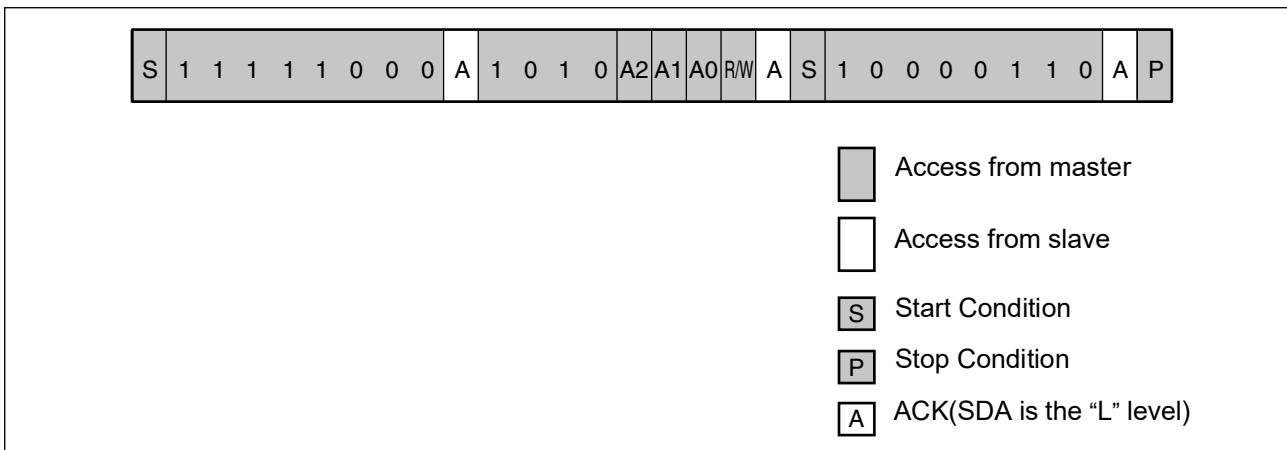
MB85RC256TY

- Sleep Mode

MB85RC256TY provides Sleep mode which reduces less current consumption than Standby mode, by stooping the internal regulator circuits. Following sequences enable the Sleep mode transition.

<Transition to Sleep mode>

- The master sends start condition followed by F8h.
- After ACK response from slave, the master sends the device address word.
In this device address word, Read/Write code is Don't care.
- After ACK response from slave, the master re-sends the start condition followed by 86h.
- The slave moves to Sleep mode after ACK response to the master.

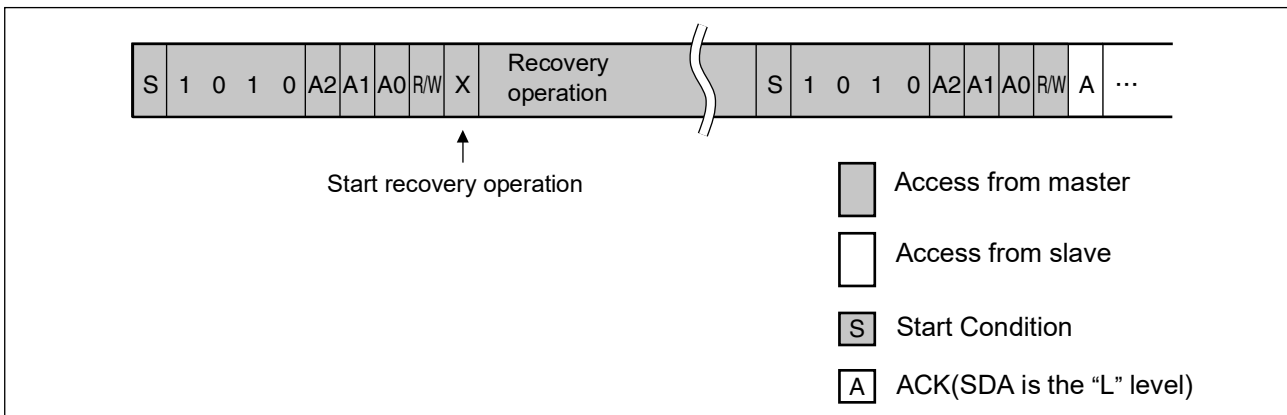


Even if the MB85RC256TY stays in the Sleep mode, SDA and SCL signals are monitored. Following sequences enable the transition to Standby mode after recovery time (t_{REC}) of internal regulator circuits.

<Exit from Sleep mode>

- The master sends start condition followed by device address word.
In this device address word, Read/Write code is Don't care.
- At the rising edge of 9th clock from start condition, an internal regulator starts to operate its recovery sequence.
- After the recovery time (t_{REC}) passed, standby mode enabled.

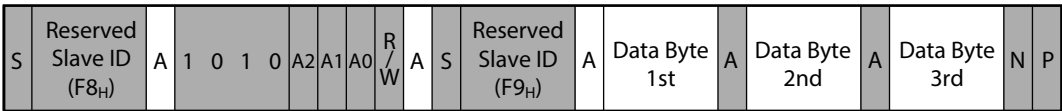
After returning to Standby mode, reading and writing are enabled by sending each command starts with start condition.



• Device ID

The Device ID command reads fixed Device ID. The size of Device ID is 3 bytes and consists of manufacturer ID and product ID. The Device ID is read-only and can be read out by following sequences.

- a) The master sends the Reserved Slave ID F8_H after the START condition.
- b) The master sends the device address word after the ACK response from the slave.
In this device address word, R/W code is "Don't care".
- c) The master re-sends the START condition followed by the Reserved Slave ID F9_H after the ACK response from the slave.
- d) The master read out the Device ID succeedingly in order of Data Byte 1st / 2nd / 3rd after the ACK response from the slave.
- e) The master responds the NACK (SDA is the "H" level) after reading 3 bytes of the Device ID.
In case the master respond the ACK after reading 3 bytes of the Device ID, the master re-reading the Device ID from the 1st byte.



- Access from master
- Access from slave
- S Start Condition
- P Stop Condition
- A ACK (SDA is the "L" level)
- N NACK (SDA is the "H" level)

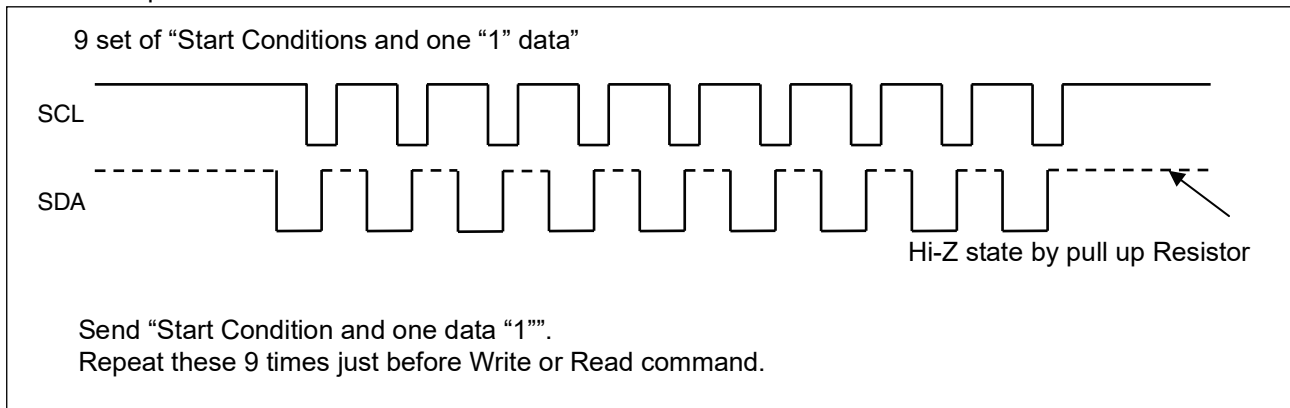
| Data Byte 1st | | | | | | | | | | | Data Byte 2nd | | | | | | | | | | Data Byte 3rd | | | | | | | | | | | | | | | | | | |
|-----------------------------------|----|---|---|---|---|---|---|---|---|---|-------------------------------|----|----|---|---|-----------------|---|---|---|---|---------------|---|---|---|---|---|---|--|--|--|--|--|--|--|--|--|--|--|--|
| Manufacture ID = 00A _H | | | | | | | | | | | Product ID = 498 _H | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | | | | | | | | | | | | | |
| | | | | | | | | | | | Density = 4 _H | | | | | Proprietary use | | | | | | | | | | | | | | | | | | | | | | | |
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | | | | | | | | | | | | |

■ SOFTWARE RESET SEQUENCE OR COMMAND RETRY

In case the malfunction has occurred after power on, the master side stopped the I²C communication during processing, or unexpected malfunction has occurred, execute the following (1) software recovery sequence just before each command, or (2) retry command just after failure of each command.

(1) Software Reset Sequence

Since the slave side may be outputting "L" level, do not force to drive "H" level, when the master side drives the SDA port. This is for preventing a bus conflict. The additional hardware is not necessary for this software reset sequence.



(2) Command Retry

Command retry is useful to recover from failure response during I²C communication.

■ ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Rating | | Unit |
|-------------------------------|-----------|--------|---------------------------|------|
| | | Min | Max | |
| Power supply voltage* | V_{DD} | - 0.5 | +4.0 | V |
| Input voltage* | V_{IN} | - 0.5 | $V_{DD} + 0.5 (\leq 4.0)$ | V |
| Output voltage* | V_{OUT} | - 0.5 | $V_{DD} + 0.5 (\leq 4.0)$ | V |
| Operation ambient temperature | T_A | - 40 | + 125 | °C |
| Storage temperature | T_{stg} | - 55 | + 125 | °C |

*: These parameters are based on the condition that VSS is 0 V.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

| Parameter | Symbol | Value | | | Unit |
|---|----------|-------|-----|-------|------|
| | | Min | Typ | Max | |
| Power supply voltage* ¹ | V_{DD} | 1.8 | 3.3 | 3.6 | V |
| Operation ambient temperature* ² | T_A | - 40 | — | + 125 | °C |

*1: These parameters are based on the condition that VSS is 0 V.

*2: Ambient temperature when only this device is working. Please consider it to be the almost same as the package surface temperature.

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics

(within recommended operating conditions)

| Parameter | Symbol | Condition | Value | | | Unit |
|---|-----------------|---|-----------------------|--------------------------------|-----------------------|------|
| | | | Min | Typ (T _A =25 °C) | Max | |
| Input leakage current*1 | I _{LI} | V _{IN} = 0 V to V _{DD} | — | — | 1 | μA |
| Output leakage current*2 | I _{LO} | V _{OUT} = 0 V to V _{DD} | — | — | 1 | μA |
| Operating power supply current | I _{DD} | SCL = 0.1 MHz | — | — | — | mA |
| | | SCL = 1 MHz | — | 0.09 | — | mA |
| | | SCL = 3.4 MHz | — | 0.23 | 0.4 | mA |
| Standby current | I _{SB} | SCL, SDA = V _{DD} A0, A1, A2, WP = 0 V or Open Under Stop Condition | — | 14 | 150 | μA |
| Sleep current | I _{ZZ} | SCL, SDA = V _{DD} A0, A1, A2, WP = 0 V | — | 0.24 | 10 | μA |
| “H” level input voltage | V _{IH} | V _{DD} = 1.8 V to 3.6 V | V _{DD} × 0.8 | — | V _{DD} +0.5 | V |
| “L” level input voltage | V _{IL} | V _{DD} = 1.8 V to 3.6 V | -0.5 | — | V _{DD} × 0.2 | V |
| “L” level output voltage | V _{OL} | I _{OL} = 3 mA | — | — | 0.4 | V |
| Input resistance for WP, A0, A1 and A2 pins | R _{IN} | — | 11 | 33 | 125 | kΩ |

*1: Applicable pin: SCL,SDA

*2: Applicable pin: SDA

2. AC Characteristics

| Parameter | Symbol | Value | | | | | | | | Unit |
|--------------------------------------|---------------------|---------------|------|-----------|-----|-------------------|-------------------|------------------|------|------|
| | | STANDARD MODE | | FAST MODE | | FAST MODE PLUS | | HIGH SPEED MODE | | |
| | | Min | Max | Min | Max | Min | Max | Min | Max | |
| SCL clock frequency | F _{SCL} | 0 | 100 | 0 | 400 | 0 | 1000 | 0 | 3400 | kHz |
| Clock high time | T _{HIGH} | 4000 | — | 600 | — | 260* ¹ | — | 60 | — | ns |
| Clock low time | T _{LOW} | 4700 | — | 1300 | — | 500* ² | — | 160 | — | ns |
| SCL/SDA rising time | T _r | — | 1000 | — | 300 | — | 300 | — | 80 | ns |
| SCL/SDA falling time | T _f | — | 300 | — | 300 | — | 120 | — | 80 | ns |
| Start condition hold | T _{HD:STA} | 4000 | — | 600 | — | 250 | — | 160 | — | ns |
| Start condition setup | T _{SU:STA} | 4700 | — | 600 | — | 250 | — | 160 | — | ns |
| SDA input hold | T _{HD:DAT} | 0 | — | 0 | — | 0 | — | 0 | — | ns |
| SDA input setup | T _{SU:DAT} | 250 | — | 100 | — | 50 | — | 16* ⁴ | — | ns |
| SDA output hold | T _{DH:DAT} | 0 | — | 0 | — | 0 | — | 0 | — | ns |
| Stop condition setup | T _{SU:STO} | 4000 | — | 600 | — | 250 | — | 160 | — | ns |
| SDA output access after SCL falling | T _{AA} | — | 3000 | — | 900 | — | 450* ³ | — | 130 | ns |
| Pre-charge time | T _{BUF} | 4700 | — | 1300 | — | 500 | — | 300 | — | ns |
| Noise suppression time (SCL and SDA) | T _{SP} | — | 50 | — | 50 | — | 50 | — | 5 | ns |

*1: 300ns @VDD ≤ 2.7 V

*2: 600ns @VDD ≤ 2.7 V

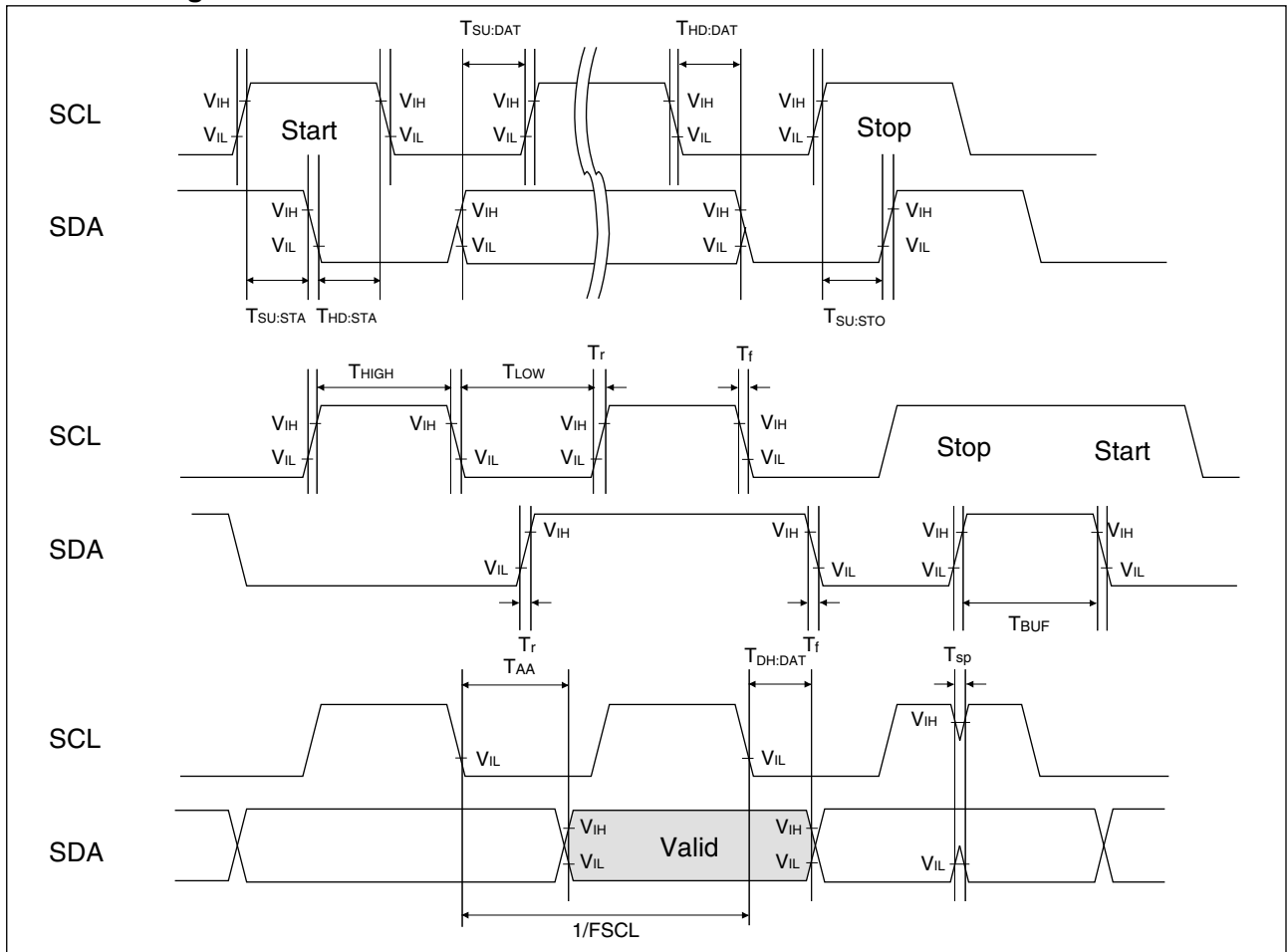
*3: 550ns @VDD ≤ 2.7 V

*4: 26ns @VDD ≤ 2.7 V

AC characteristics were measured under the following measurement conditions.

| | |
|-------------------------------|--|
| Power supply voltage | : 1.8 V to 3.6 V |
| Operation ambient temperature | : - 40 °C to + 125 °C |
| Input voltage magnitude | : V _{DD} × 0.2 to V _{DD} × 0.8 |
| Input rising time | : 5 ns |
| Input falling time | : 5 ns |
| Input judge level | : V _{DD} /2 |
| Output judge level | : V _{DD} /2 |
| Output load capacitance | : 100 pF |

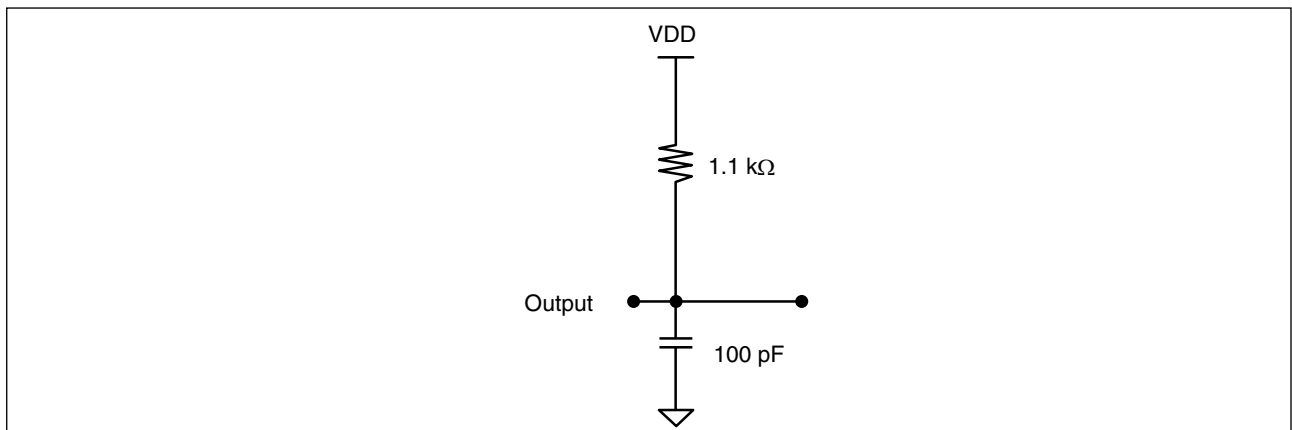
3. AC Timing Definitions



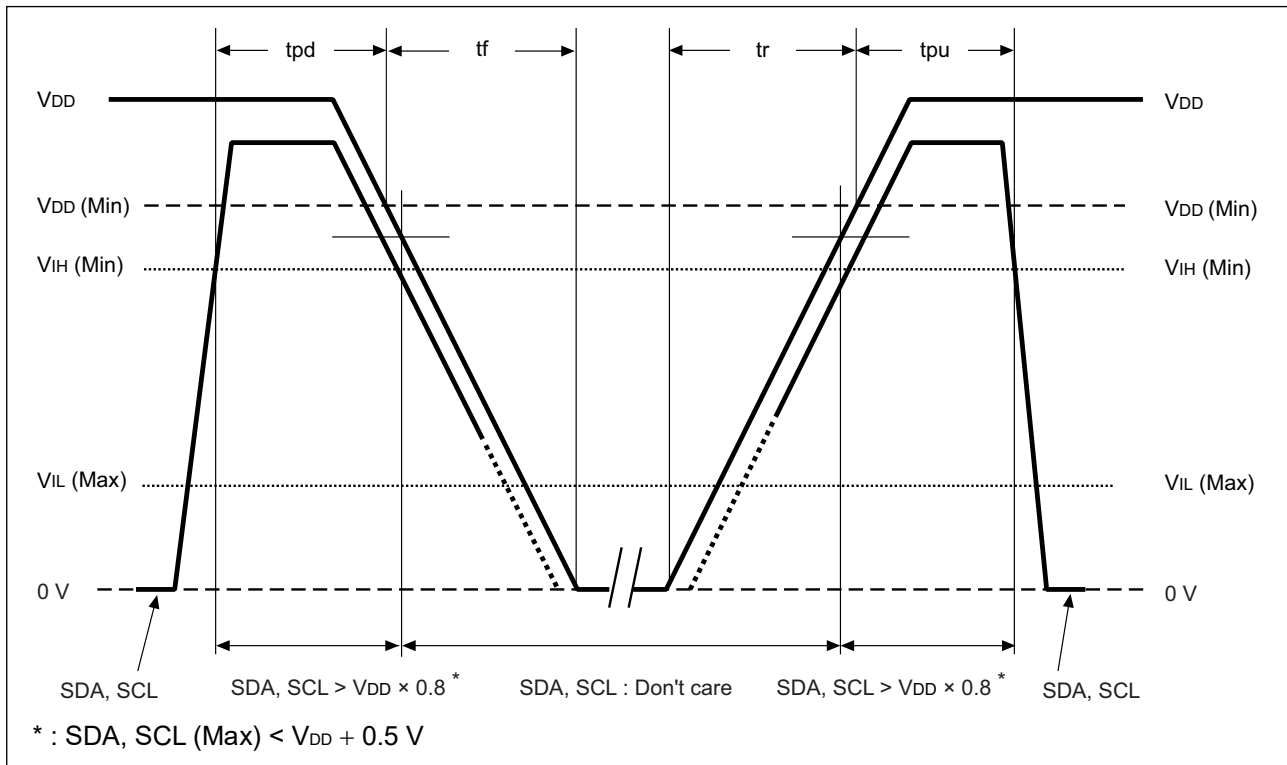
4. Pin Capacitance

| Parameter | Symbol | Conditions | Value | | | Unit |
|-------------------|-----------|---|-------|-----|-----|------|
| | | | Min | Typ | Max | |
| I/O capacitance | $C_{I/O}$ | $V_{DD} = 3.3\text{ V}$, $f = 1\text{ MHz}$, $T_A = +25\text{ }^\circ\text{C}$ | — | — | 8 | pF |
| Input capacitance | C_{IN} | | — | — | 8 | pF |

5. AC Test Load Circuit



■ POWER ON/OFF SEQUENCE



When applying relatively short term V_{DD} pulse whose peak is more than 1.7V, it is required to set falling time, tf more than 0.4ms/V. (In case V_{DD} rises over 1.7V and falls just after that, if this term is short, device may lose its function.)

| Parameter | Symbol | Value | | Unit |
|--|------------------|-------|-----|------|
| | | Min | Max | |
| SDA, SCL level hold time during power down | tpd | 85 | — | ns |
| SDA, SCL level hold time during power up | tpu | 450 | — | μs |
| Power supply rising time | tr | 0.05 | — | ms/V |
| Power supply falling time | tf | 0.1 | — | ms/V |
| Internal regulator recovery time | t _{REC} | — | 450 | μs |

If the device does not operate within the specified conditions of read cycle, write cycle or power on/off sequence, memory data can not be guaranteed.

■ FeRAM CHARACTERISTICS

| Item | Min | Max | Unit | Parameter |
|------------------------|------------------|-----|-------|---|
| Read/Write Endurance*1 | 10 ¹³ | — | Times | Operation Ambient Temperature T _A = + 125 °C |
| | 10 ¹⁴ | — | | Operation Ambient Temperature T _A = + 85 °C |
| Data Retention*2 | 10.1*3 | — | Years | Operation Ambient Temperature T _A = + 125 °C |
| | 40.7 | — | | Operation Ambient Temperature T _A = + 105 °C |
| | 193.9 | — | | Operation Ambient Temperature T _A = + 85 °C |

*1: The value for Read/Write endurance apply to the total number of read and write operations per row in FeRAM. This is because FeRAM needs writing operation after each reading operations.

*2: Minimum values define retention time of the first reading/writing data right after shipment.

*3: Under evaluation for more than 10.1 years(+125 °C). These values are calculated by qualification results.

MB85RC256TY

■ NOTE ON USE

- We recommend programming of the device after reflow. Data written before reflow cannot be guaranteed.
- During the access period from the start condition to the stop condition, keep the level of WP, A0, A1 and A2 pins to the “H” level or the “L” level.

■ ESD AND LATCH-UP

| Test | DUT | Value |
|--|--|------------------------|
| ESD HBM (Human Body Model) JESD22-A114 compliant | MB85RC256TYPNF-G-BCE1 MB85RC256TYPNF-G-BCERE1 MB85RC256TYPN-G-AWE1 MB85RC256TYPN-G-AWEWE1 | $\geq 2000\text{ V} $ |
| ESD CDM (Charged Device Model) JESD22-C101 compliant | | $\geq 1000\text{ V} $ |
| Latch-Up (I-test) JESD78 compliant | | $\geq 125\text{mA} $ |
| Latch-Up (V_{supply} overvoltage test) JESD78 compliant | | $\geq 5.4\text{V}$ |

■ REFLOW CONDITIONS AND FLOOR LIFE

[JEDEC MSL] : Moisture Sensitivity Level 3 (IPC/JEDEC J-STD-020E)

■ CURRENT STATUS ON CONTAINED RESTRICTED SUBSTANCES

This product complies with the regulations of REACH Regulations, EU RoHS Directive and China RoHS.

■ ORDERING INFORMATION

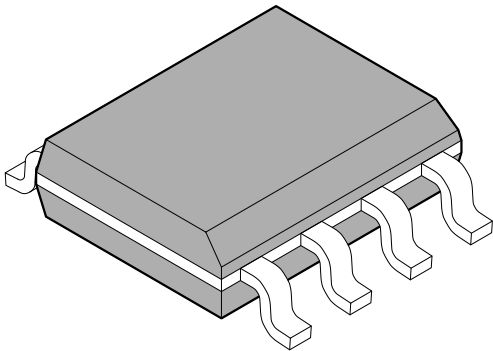
| Part number | Package | Shipping form | Minimum shipping quantity |
|-------------------------|--------------------------------|--------------------------|---------------------------|
| MB85RC256TYPNF-G-BCE1 | 8-pin, plastic SOP (150mil) | Tube | —* |
| MB85RC256TYPNF-G-BCERE1 | 8-pin, plastic SOP (150mil) | Embossed Carrier tape | 1500 |
| MB85RC256TYPN-G-AWE1 | 8-pin, plastic DFN | Tray | —* |
| MB85RC256TYPN-G-AWEWE1 | 8-pin, plastic DFN | Embossed Carrier tape | 1500 |

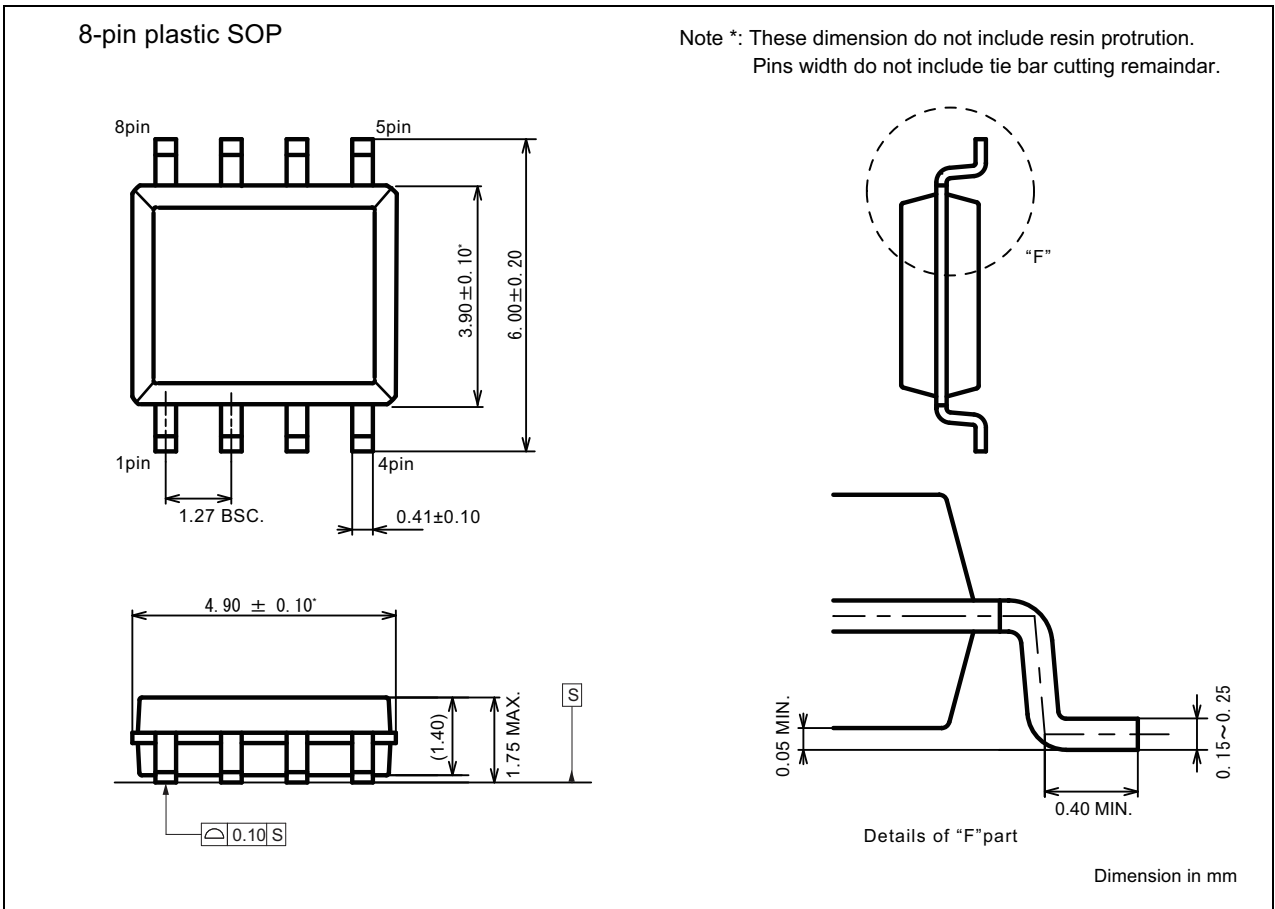
*: Please contact our sales office about minimum shipping quantity.

MB85RC256TY

■ PACKAGE DIMENSION

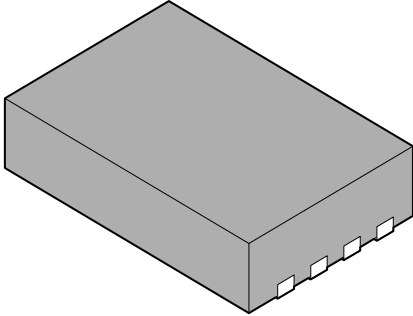
(1) MB85RC256TYPNF-G-BCE1/MB85RC256TYPNF-G-BCERE1

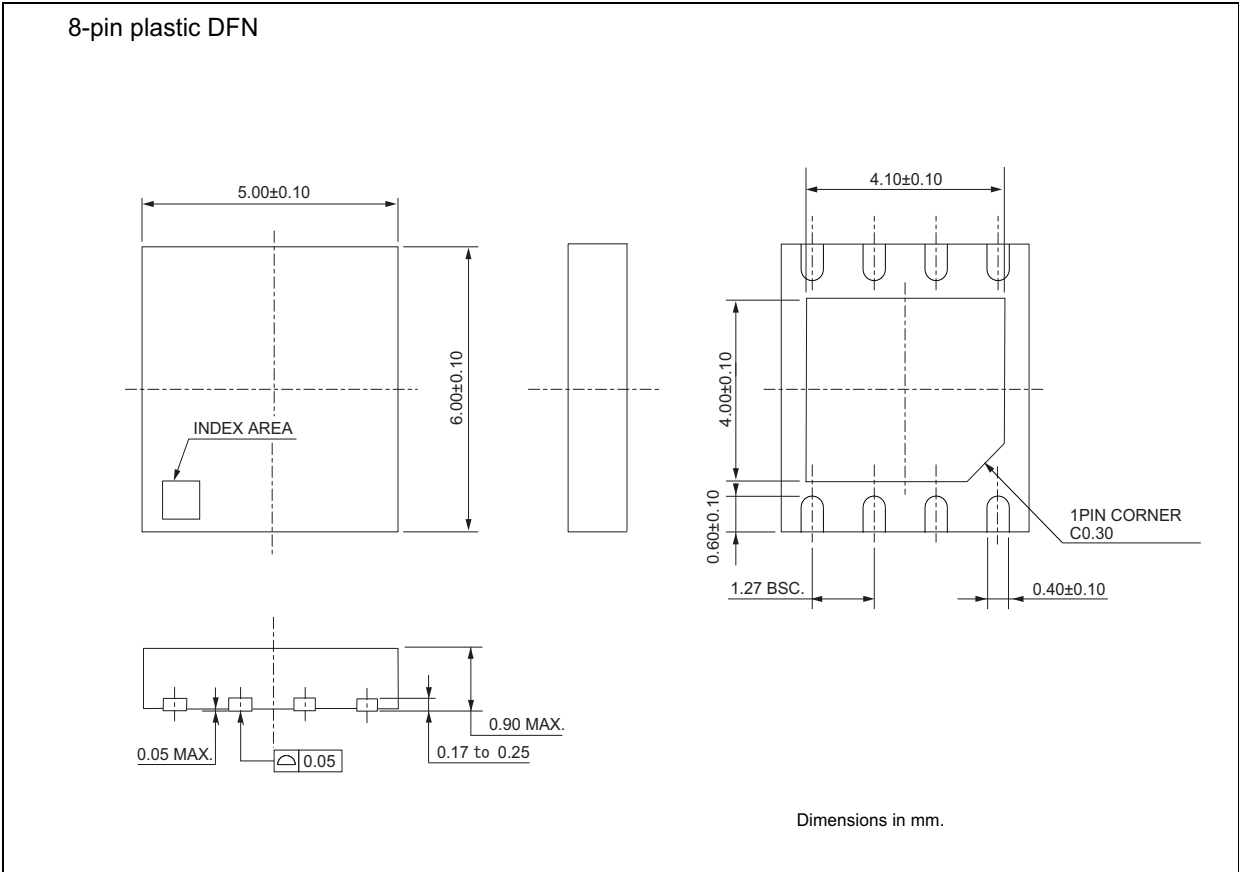
| | | | |
|--|--------------------------------|-----------------|--|
|  <p>8-pin plastic SOP(150mil)</p> | Lead pitch | 1.27mm | |
| | Package width x Package length | 3.90mm x 4.90mm | |
| | Lead shape | Gullwing | |
| | Sealing method | Plastic mold | |
| | Mounting height | 1.75mm MAX. | |
| | | | |
| | | | |



MB85RC256TY

(2) MB85RC256TYPN-G-AWE1/MB85RC256TYPN-G-AWEWE1

| | | |
|--|--------------------------------|-------------------|
| <p>8-pin plastic DFN</p>  | Lead pitch | 1.27 mm |
| | Package width x Package length | 5.00 mm × 6.00 mm |
| | Sealing method | Plastic mold |
| | Mounting height | 0.90 mm MAX |
| | | |



MB85RC256TY

■ MARKING (Example)

(1) MB85RC256TYPNF-G-BCE1/MB85RC256TYPNF-G-BCERE1

[MB85RC256TYPNF-G-BCE1]
[MB85RC256TYPNF-G-BCERE1]

C 2 5 T Y
1 2 3 0 0
V 0 1

8-pin, plastic, SOP, 150mil

C25TY: Product name
12300 : 1(CS code) + 2300(Year and Week code)
V01 : Trace code

The diagram shows a square marking area for an 8-pin plastic SOP package. At the top, two reference codes are listed: [MB85RC256TYPNF-G-BCE1] and [MB85RC256TYPNF-G-BCERE1]. The main marking consists of three rows of characters: 'C 2 5 T Y', '1 2 3 0 0', and 'V 0 1'. A small circle is located at the bottom left of the marking area. Below the marking area, the package type '8-pin, plastic, SOP, 150mil' is specified, followed by a legend for the characters: 'C25TY' is the product name, '12300' is composed of CS code '1' and Year/Week code '2300', and 'V01' is the trace code.

(2) MB85RC256TYPN-G-AWE1/MB85RC256TYPN-G-AWEWE1

[MB85RC256TYPN-G-AWE1]
[MB85RC256TYPN-G-AWEWE1]

85RC256TY
1E1 2300R00

8-pin, plastic, DFN, 5mm x 6mm

85RC256TY: Product name
1E1 : 1(CS code) + E1(Lead free code)
2300R00 : 2300(Year and Week code) + R00(Trace code)

The diagram shows a square marking area for an 8-pin plastic DFN package. At the top, two reference codes are listed: [MB85RC256TYPN-G-AWE1] and [MB85RC256TYPN-G-AWEWE1]. The main marking consists of two rows of characters: '85RC256TY' and '1E1 2300R00'. A solid black circle is located at the top left of the marking area. Below the marking area, the package type '8-pin, plastic, DFN, 5mm x 6mm' is specified, followed by a legend for the characters: '85RC256TY' is the product name, '1E1' is composed of CS code '1' and Lead free code 'E1', and '2300R00' is composed of Year/Week code '2300' and Trace code 'R00'.

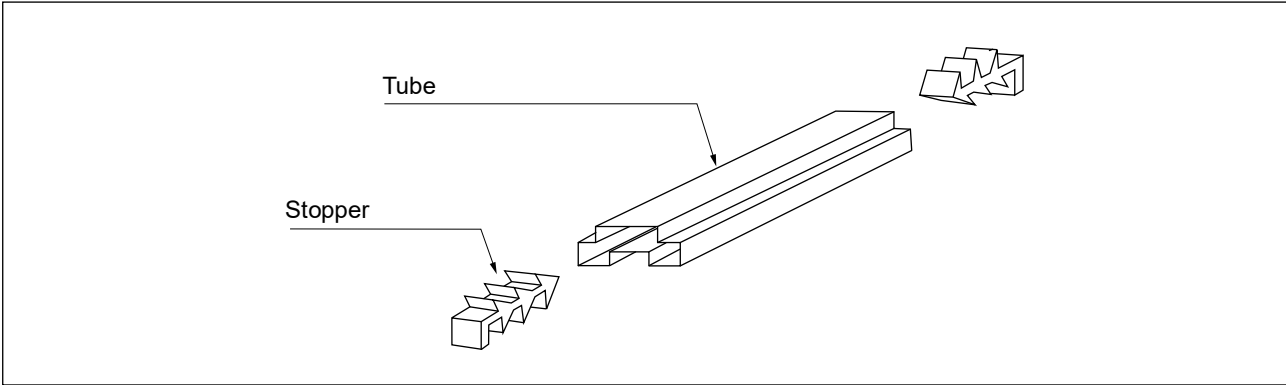
■ PACKING INFORMATION

(1) MB85RC256TYPNF-G-BCE1/MB85RC256TYPNF-G-BCERE1

1. Tube (MB85RC256TYPNF-G-BCE1)

1.1 Tube Dimensions

- Tube/stopper shape (example)



- Tube cross-sections and Maximum quantity

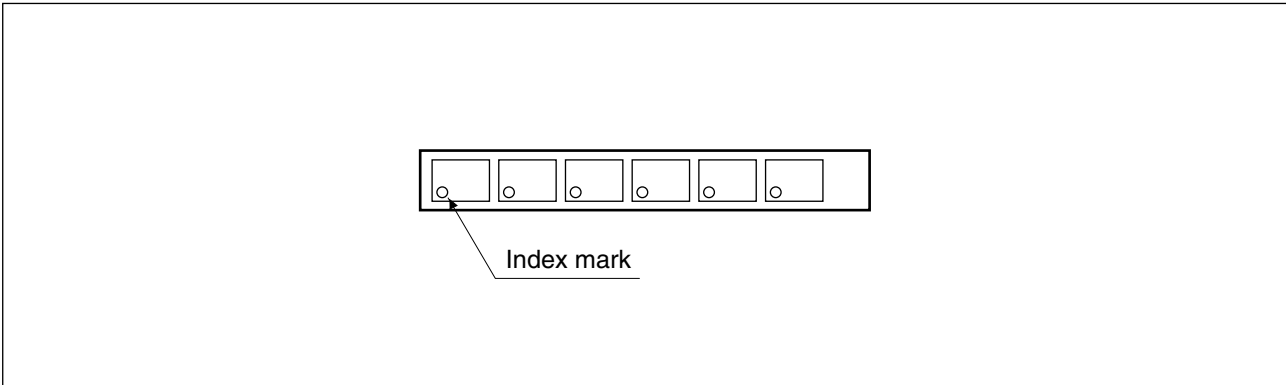
| Maximum quantity | | |
|------------------|---------------|---------------|
| pcs/tube | pcs/inner box | pcs/outer box |
| 85 | 4,250 | 17,000 |

tube length: 500

No heat resistance.
Package should not be baked by using tube.

(Dimensions in mm)

- Direction of index in tube



MB85RC256TY

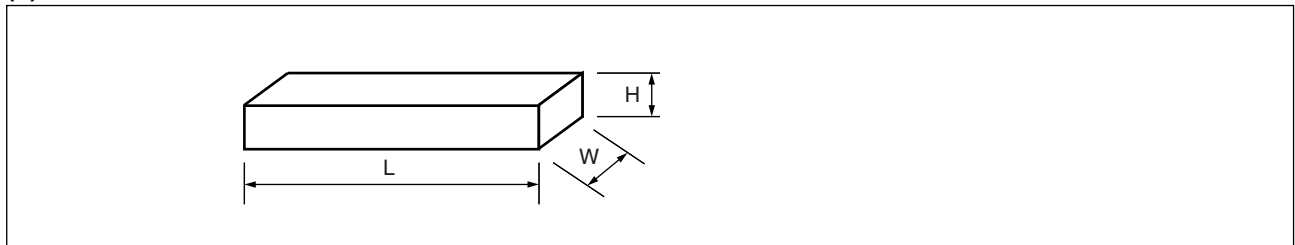
1.2 Product label indicators (example)

Label I: Label on Inner box/Moisture Barrier Bag/ (It sticks it on the reel for the emboss tapping)
 [C-3 Label (50mm × 100mm) Supplemental Label (20mm × 100mm)]

| | | |
|---|---------------------------|----------------------|
| XXXXXXXXXXXXXXXXX (Part number) | | ← C-3 Label |
| (3N)1 XXXXXXXXXXXXXXXX XXX (Part number and quantity) | (LEAD FREE mark) | |
| | QC PASS | |
| (3N)2 XXXXXXXXXXXXXXXX XXXXXX (Control number bar code) | | |
| | | |
| XXX pcs (Quantity) | | |
| XXXXXXXXXXXXXXXXX (Part number) | | |
| | | |
| XXXX/XX/XX (Packed years/month/day) | ASSEMBLED IN xxxx | ← Perforated line |
| XXXXXXXXXXXXXXXXX (Part number) | | ← Supplemental Label |
| (Control number bar code) | | |
| | XX/XX (Package count) | XXXX-XXX XXX |
| XXXXXXXXXXXX (Control number) | | XXXX-XXX XXX |
| XXXXXXXXXXXXXXXXX (Comment) | (Lot Number and quantity) | |

1.3 Dimensions for Containers

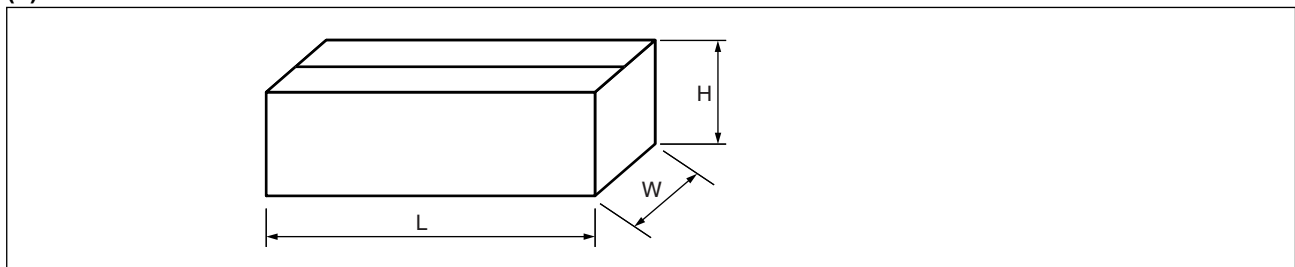
(1) Dimensions for inner box



| L | W | H |
|-----|-----|----|
| 540 | 125 | 75 |

(Dimensions in mm)

(2) Dimensions for outer box

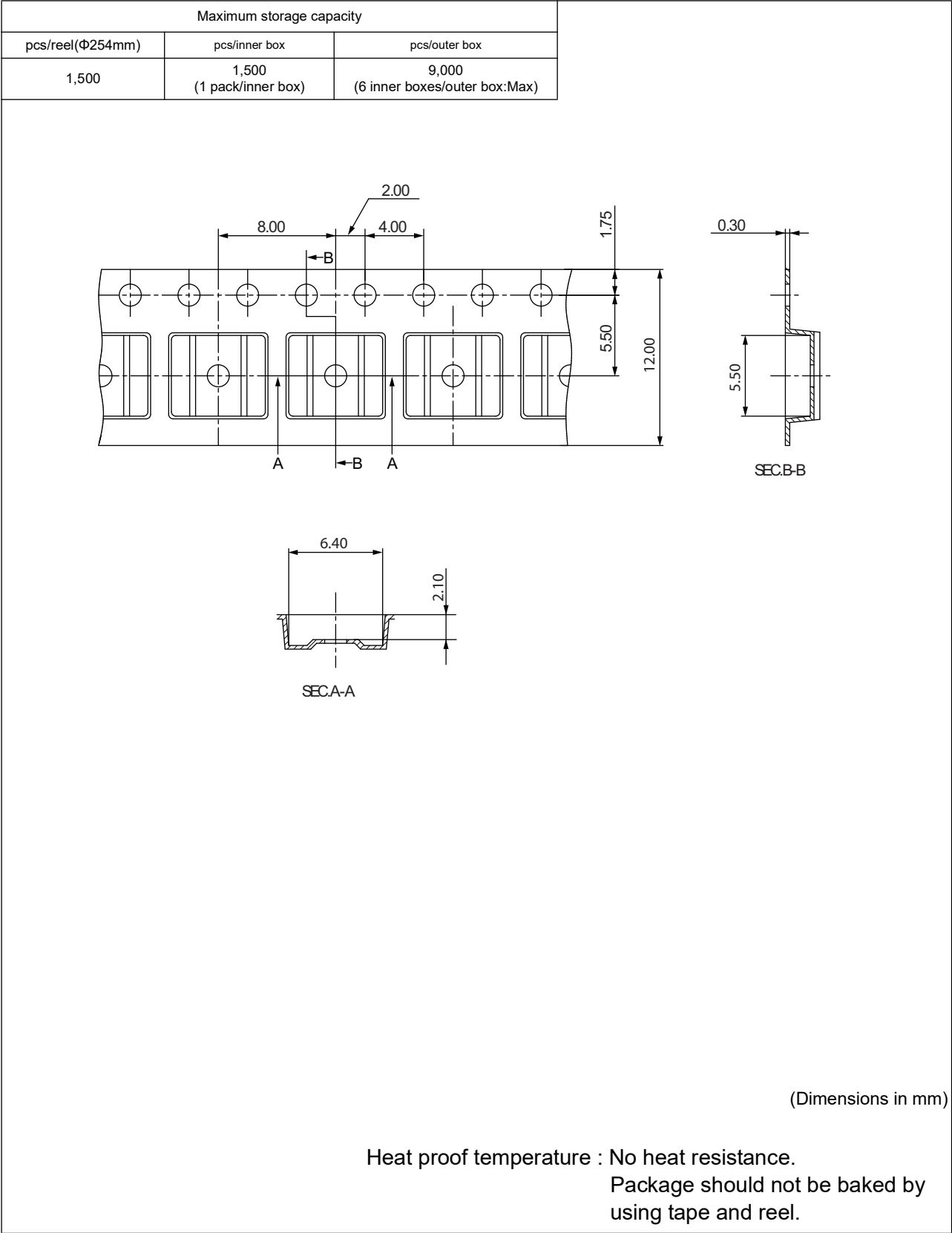


| L | W | H |
|-----|-----|-----|
| 565 | 270 | 180 |

(Dimensions in mm)

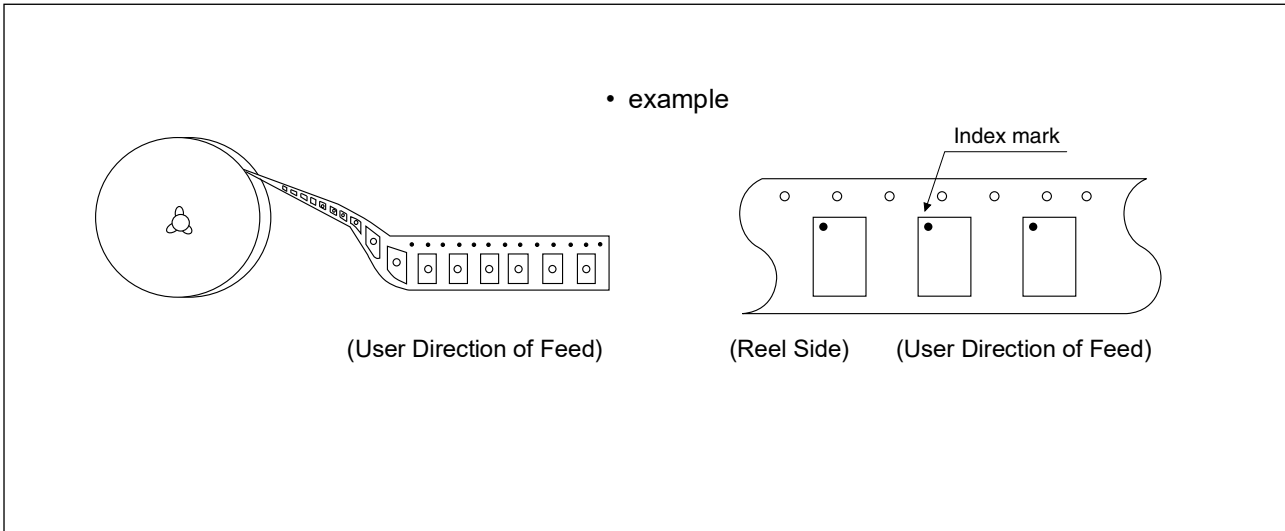
2. Emboss Tape (MB85RC256TYPNF-G-BCERE1)

2.1 Tape Dimensions (not drawn to scale) (8-pin plastic SOP, 150mil)

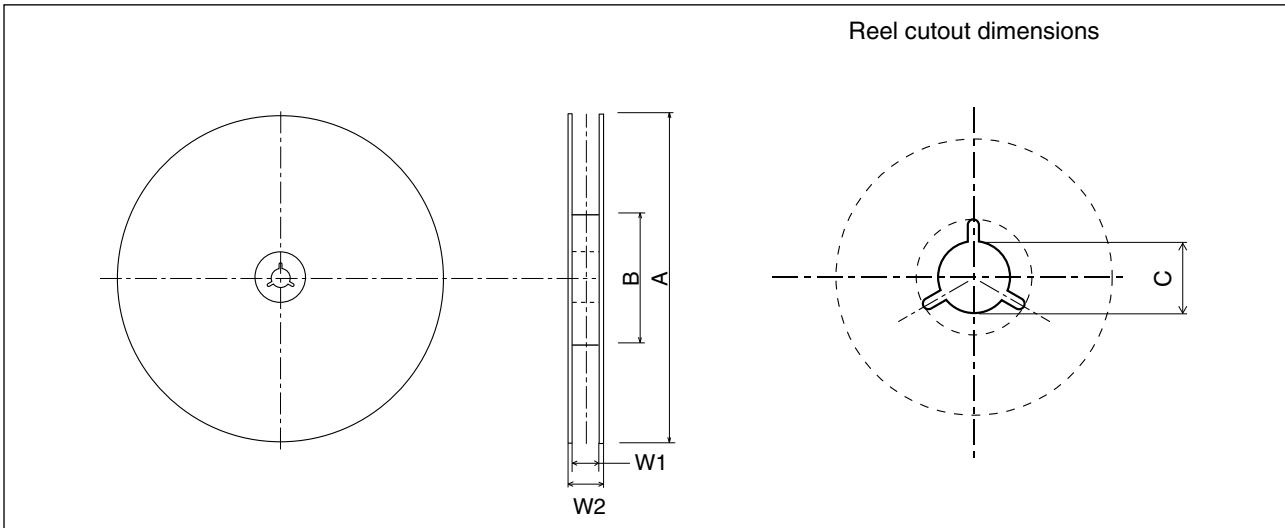


MB85RC256TY

2.2 IC orientation



2.3 Reel dimensions



Dimensions in mm

| A | B | C | W1 | W2 |
|-----|-----|----|------|------|
| 254 | 100 | 13 | 13.5 | 17.5 |

2.4 Product label indicators (examples)

Label I: Label on Inner box/Moisture Barrier Bag/ (It sticks it on the reel for the emboss taping)
 [C-3 Label (50mm × 100mm) Supplemental Label (20mm × 100mm)]

| | | |
|--|---------|----------------------|
| XXXXXXXXXXXXXX (Part number) | | ← C-3 Label |
| (3N)1 XXXXXXXXXXXXXXXX XXX (LEAD FREE mark) (Part number and quantity) | QC PASS | |
| (3N)2 XXXXXXXXXXXXXXXX XXXXXX (Control number bar code) | | |
| XXX pcs (Quantity) XXXXXXXXXXXXXXXXXXXX (Part number) | | |
| XXXXXXXXXXXXXXXXXXXX (Part number bar code) | | |
| XXXX/XX/XX (Packed years/month/day) ASSEMBLED IN xxxx | | ← Perforated line |
| XXXXXXXXXXXXXXXXXXXX (Part number) (Control number bar code) | | ← Supplemental Label |
| XX/XX (Package count) XXXX-XXX XXX XXXXXXXXXXXX (Control number) XXXX-XXX XXX XXXXXXXXXXXXXXXXXXXX (Comment) | | |

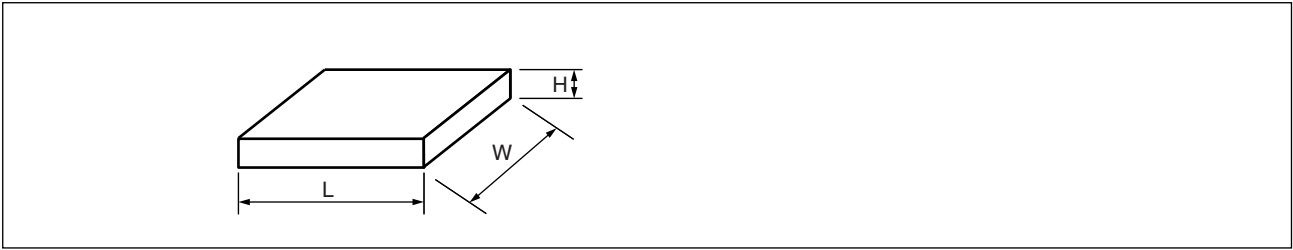
Label II: Moisture Barrier Bag (It sticks it on the Aluminum laminated bag)
 [MSL Label]

| | |
|---|-------------|
| <p>Caution This bag contains MOISTURE-SENSITIVE DEVICES</p> <p>LEVEL 3</p> <ol style="list-style-type: none"> 1. Calculated shelf life in sealed bag: 24 months at <40°C and <90% relative humidity (RH) 2. Peak package body temperature: 260°C 3. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must be <ol style="list-style-type: none"> a) Mounted within: 168 hours of factory conditions <30°C/60% RH, or b) Stored per J-STD-033 4. Devices require bake, before mounting, if: <ol style="list-style-type: none"> a) Humidity Indicator Card reads >10% for level 2a - 5a devices or >60% for level 2 devices when read at 23 ± 5°C b) 3a or 3b are not met 5. If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure <p>Bag Seal Date: see adjacent bar code label.</p> <p>Note: Level and body temperature defined by IPC/JEDEC J-STD-020</p> | ← MSL label |
|---|-------------|

MB85RC256TY

2.5 Dimensions for Containers

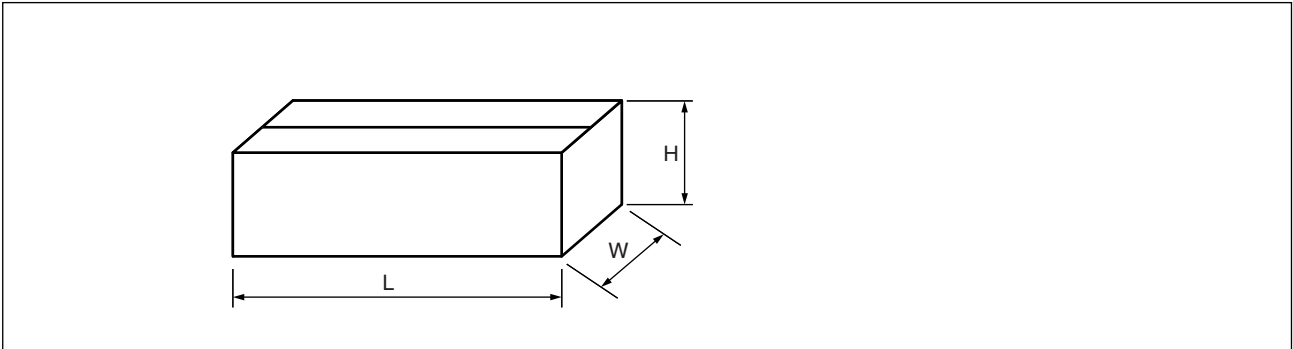
(1) Dimensions for inner box



| Tape width | L | W | H |
|------------|-----|-----|----|
| 12 | 265 | 260 | 50 |

(Dimensions in mm)

(2) Dimensions for outer box



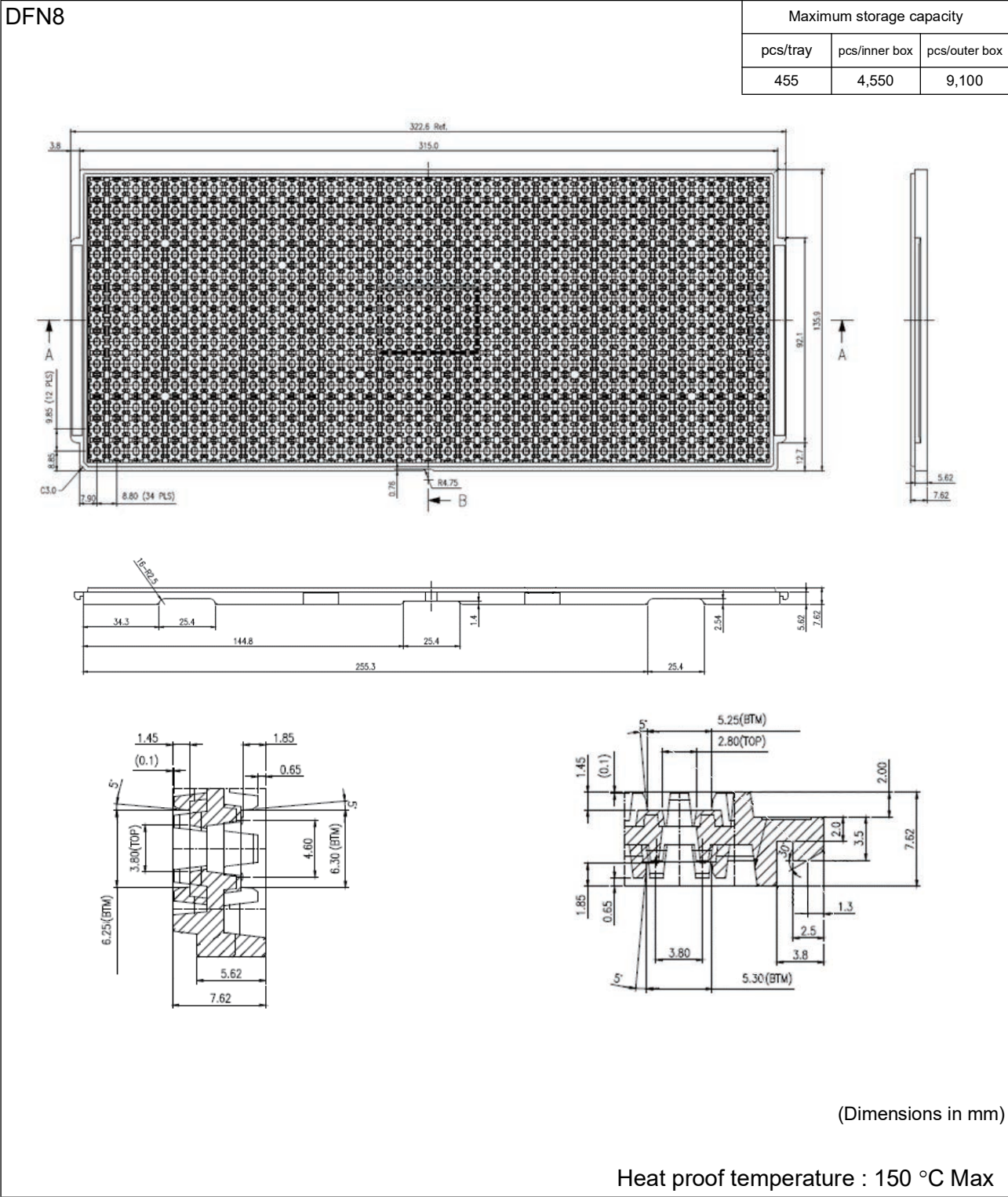
| L | W | H |
|-----|-----|-----|
| 565 | 270 | 180 |

(Dimensions in mm)

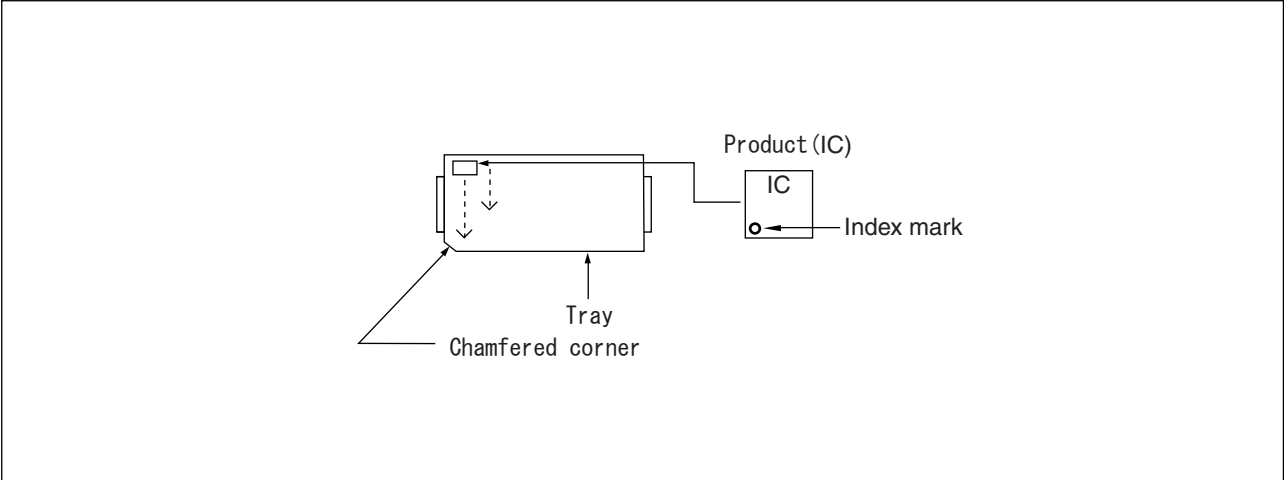
(2) MB85RC256TYPN-G-AWE1/MB85RC256TYPN-G-AWEWE1

1. Tray (MB85RC256TYPN-G-AWE1)

1.1 Tray Dimensions



1.2 IC orientation



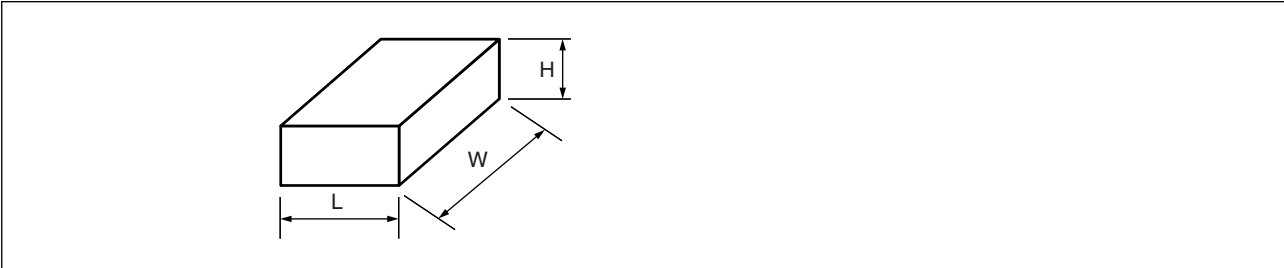
1.3 Product label indicators(example)

Label I: Label on Inner box/Moisture Barrier Bag/ (It sticks it on the reel for the emboss taping)
 [C-3 Label (50mm × 100mm) Supplemental Label (20mm × 100mm)]

| | |
|---|--|
| XXXXXXXXXXXXXXXX (Part number) (3N)1 XXXXXXXXXXXXXXXX XXX (LEAD FREE mark) (Part number and quantity) QC PASS (3N)2 XXXXXXXXXXXXXXXX XXXXXX (Control number bar code) XXX pcs (Quantity) XXXXXXXXXXXXXXXX (Part number) (Part number bar code) XXXX/XX/XX (Packed years/month/day) ASSEMBLED IN xxxx | ← C-3 Label ← Perforated line ← Supplemental Label |
| XXXXXXXXXXXXXXXX (Part number) (Control number bar code) XX/XX (Package count) XXXX-XXX XXX XXXXXXXXXXXXXXXX (Control number) XXXX-XXX XXX XXXXXXXXXXXXXXXX (Lot Number and quantity) XXXXXXXXXXXXXXXX (Comment) | |

1.4 Dimensions for Containers

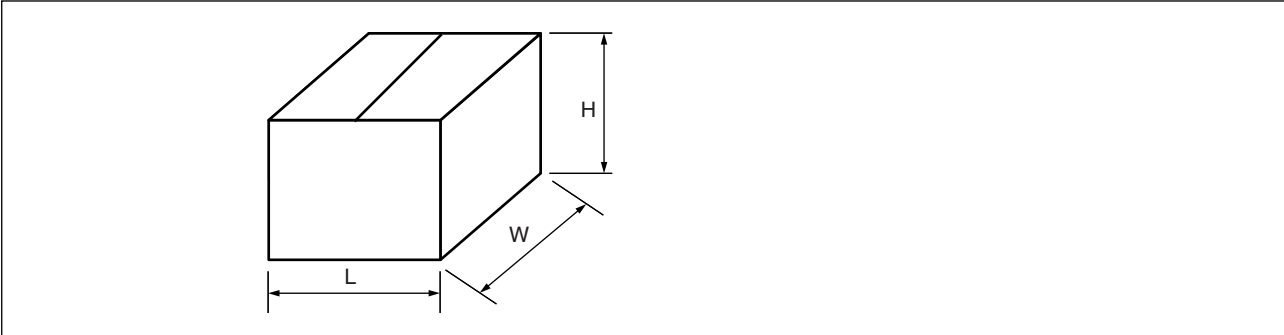
(1) Dimensions for inner box



| | | |
|-----|-----|-----|
| L | W | H |
| 175 | 375 | 110 |

(Dimensions in mm)

(2) Dimensions for outer box



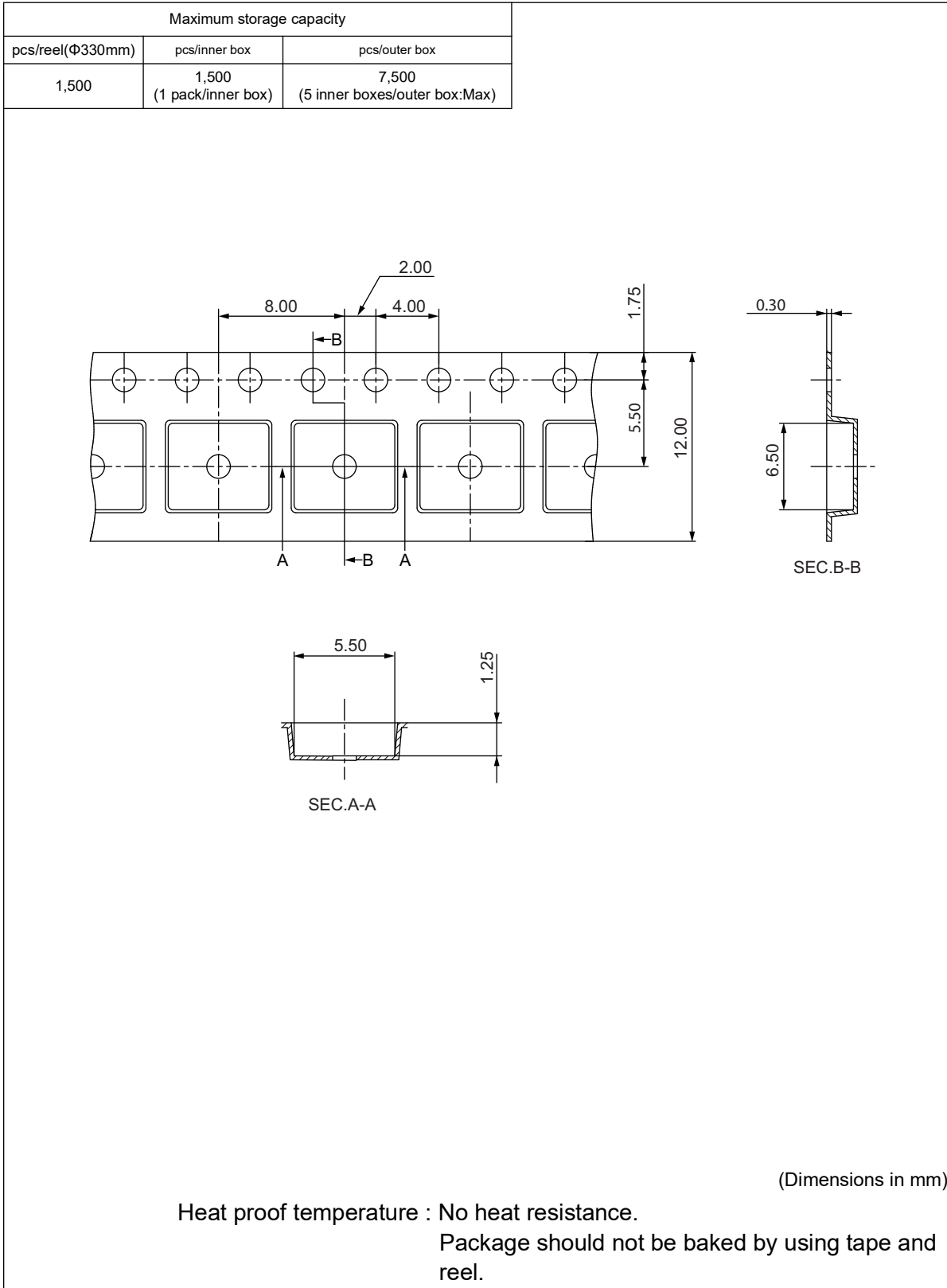
| | | |
|-----|-----|-----|
| L | W | H |
| 190 | 380 | 330 |

(Dimensions in mm)

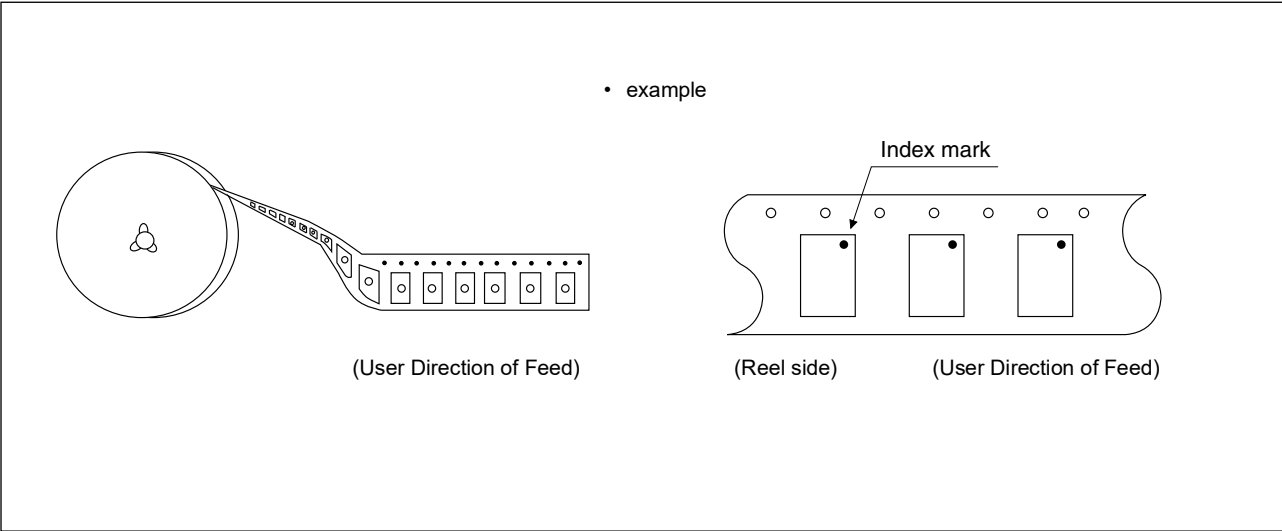
MB85RC256TY

2. Emboss Tape (MB85RC256TYPN-G-AWEWE1)

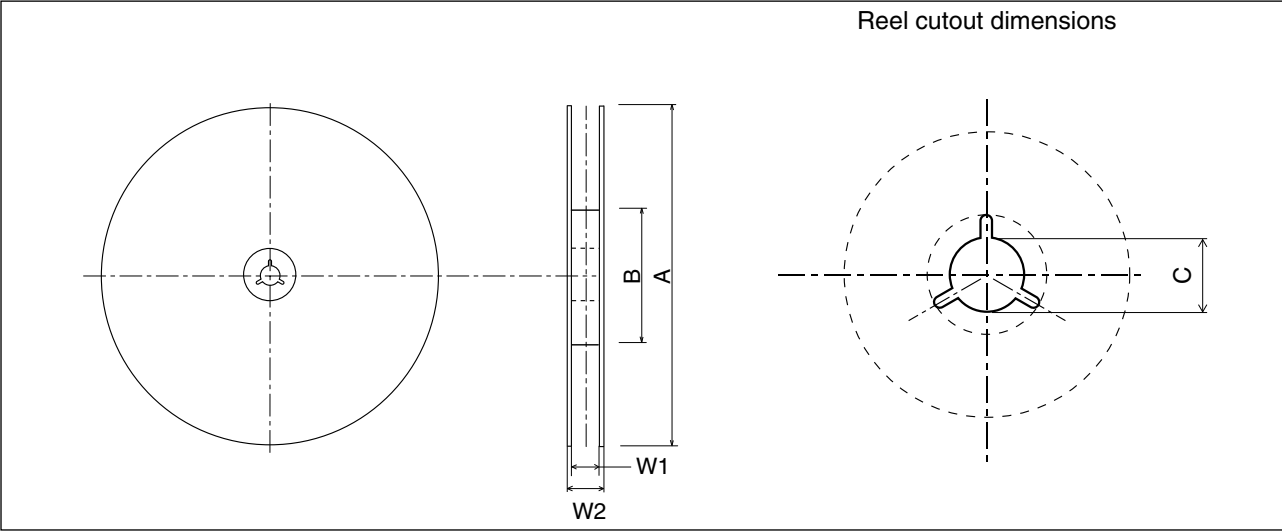
2.1 Tape Dimensions (not drawn to scale)(8-pin plastic DFN 5mm × 6mm)



2.2 IC orientation



2.3 Reel dimensions







Dimensions in mm

| A | B | C | W1 | W2 |
|-----|-----|----|------|------|
| 330 | 100 | 13 | 13.5 | 17.5 |

MB85RC256TY

2.4 Product label indicators (example)

Label I: Label on Inner box/Moisture Barrier Bag/ (It sticks it on the reel for the emboss tapping)
 [C-3 Label (50mm × 100mm) Supplemental Label (20mm × 100mm)]

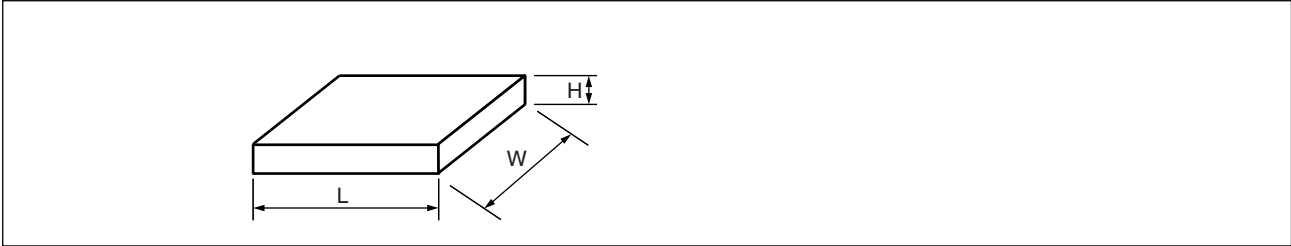
| | | | |
|---|---------------------------------------|---------------------------|----------------------|
| XXXXXXXXXXXXXX | (Part number) | G (Pb) | ← C-3 Label |
| (3N)1 XXXXXXXXXXXXXXXX | XXX (Part number and quantity) | (LEAD FREE mark) | |
|  | | QC PASS | |
| (3N)2 XXXXXXXXXXXXXXXX | XXXXXX (Control number bar code) | | |
|  | | | |
| XXX pcs (Quantity) | XXXXXXXXXXXXXX (Part number) | | |
|  | XXXXXXXXXXXXXX (Part number bar code) | | |
| XXXX/XX/XX (Packed years/month/day) | ASSEMBLED IN xxxx | | ← Perforated line |
| XXXXXXXXXXXXXX (Part number) | | | ← Supplemental Label |
| XXXXXXXXXXXXXX (Control number bar code) | | | |
|  | XX/XX (Package count) | XXXX-XXX XXX | |
| XXXXXXXXXXXXXX (Control number) | | XXXX-XXX XXX | |
| XXXXXXXXXXXXXX (Comment) | | (Lot Number and quantity) | |

Label II: Moisture Barrier Bag (It sticks it on the Aluminum laminated bag)
 [MSL Label]

| | | |
|---|--|-------------|
| MOISTURE-SENSITIVE DEVICES 注意 1. ドライパック包装の保管期限は、24 ヶ月 (25℃/80%RH未満) です。 2. 本製品の耐熱温度は、 <u>260℃</u> です。 3. 袋開封後は、下記a) b)条件下で、ご使用ください。 a) <u>168</u> 時間以内 (30℃/60%RH以下) b) J-STD-033条件 4. 以下の条件の場合は、実装前にベークしてください。 a) 23±5℃の環境下でインジケータカードの10%を超えた場合 b) 3a、3bの条件に合致しない場合 5. ベーク必要な場合はIPC/JEDEC J-STD-033 参照してください。 | LEVEL <div style="border: 1px solid black; padding: 5px; display: inline-block; font-size: 2em; font-weight: bold;">3</div> | ← MSL label |
| CAUTION 1. Calculated shelf life in sealed bag: 24 months at <25℃ / 80% RH 2. Peak package body temperature: <u>260℃</u> 3. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must a) Mounted within: <u>168 hours</u> of factory conditions ≤30℃/60%RH b) Stored per J-STD-033 4. Devices require bake, before mounting, if: a) Humidity Indicator Card is > 10% when read at 23±5℃ b) 3a or 3b not met. 5. If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure. |  | |
| 包装日：品名ラベルをご確認下さい Bag Seal Date: See adjacent bar code label |  * F 0 0 0 1 * | |
| Note: Level and body temperature defined by IPC/JEDEC J-STD-020 | | |

2.5 Dimensions for Containers

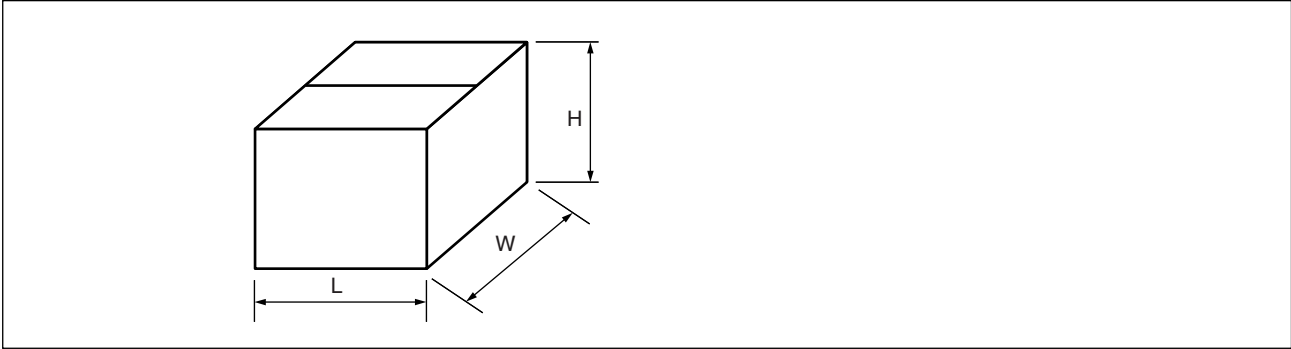
(1) Dimensions for inner box



| Tape width | L | W | H |
|-------------------|----------|----------|----------|
| 12 | 350 | 335 | 35 |

(Dimensions in mm)

(2) Dimensions for outer box



| L | W | H |
|----------|----------|----------|
| 384 | 368 | 225 |

(Dimensions in mm)

■ MAJOR CHANGES IN THIS EDITION

A change on a page is indicated by a vertical line drawn left side of that page.

| Page | Section | Change Results |
|------|----------------|--|
| 1,17 | Data Retention | 10.1 years(+125 °C), 40.7 years(+105 °C), 193.9 years(+85 °C) |

MB85RC256TY

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<https://ramxeed.com/>

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